

TLC1078, TLC1078Y, TLC1079, TLC1079Y LinCMOS™ μ POWER PRECISION OPERATIONAL AMPLIFIERS

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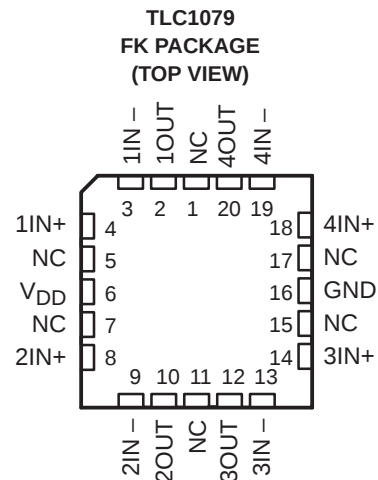
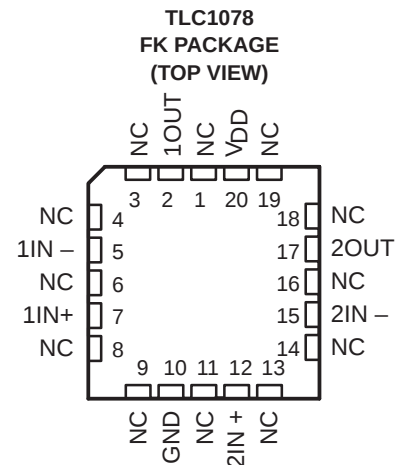
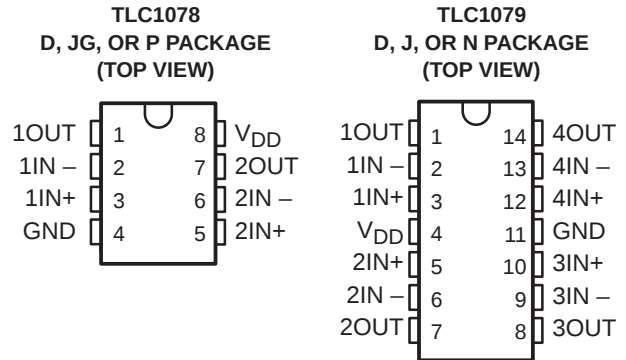
- Power Dissipation as Low as 10 μ W Typ Per Amplifier
- Operates on a Single Silver-Oxide Watch Battery, $V_{DD} = 1.4$ V Min
- $V_{IO} \dots 450 \mu\text{V}/850 \mu\text{V}$ Max in DIP and Small-Outline Package (TLC1078/79)
- Input Offset Voltage Drift $\dots 0.1 \mu\text{V}/\text{Month}$ Typ, Including the First 30 Days
- High-impedance LinCMOS™ Inputs
 $I_{IB} = 0.6$ pA Typ
- High Open-Loop Gain $\dots 800\,000$ Typ
- Output Drive Capability > 20 mA
- Slew Rate $\dots 47$ V/ms Typ
- Common-Mode Input Voltage Range Extends Below the Negative Rail
- Output Voltage Range Includes Negative Rail
- On-Chip ESD-Protection Circuitry
- Small-Outline Package Option Also Available in Tape and Reel

description

The TLC107x operational amplifiers offer ultra-low offset voltage, high gain, 110-kHz bandwidth, 47-V/ms slew rate, and just 150- μ W power dissipation per amplifier.

With a supply voltage of 1.4 V, common-mode input to the negative rail, and output swing to the negative rail, the TLC107xC is an ideal solution for low-voltage battery-operated systems. The 20-mA output drive capability means that the TLC107x can easily drive small resistive and large capacitive loads when needed, while maintaining ultra-low standby power dissipation.

Since this device is functionally compatible as well as pin compatible with the TLC27L2/4 and TLC27L7/9, the TLC107x easily upgrades existing designs that can benefit from its improved performance.



NC – No internal connection



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description (continued)

The TLC107x incorporates internal ESD-protection circuits that will prevent functional failures at voltages up to 2000 V as tested under MIL-PRF-38535, Method 3015.2; however, care should be exercised when handling these devices as exposure to ESD may result in degradation of the device parametric performance. The TLC107x design also inhibits latch-up of the device inputs and outputs even with surge currents as large 100 mA.

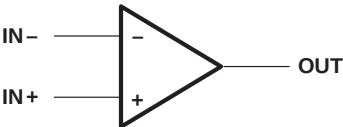
The C-suffix devices are characterized for operation from 0°C to 70°C. The I-suffix devices are characterized for operation from –40°C to 85°C. The M-suffix devices are characterized for operation over the full military temperature range of –55°C to 125°C. The wide range of packaging options includes small-outline and chip-carrier versions for high-density system applications.

AVAILABLE OPTIONS							
T _A	PACKAGED DEVICES						CHIP FORM [‡] (Y)
	SMALL OUTLINE [†] (D)	CHIP CARRIER (FK)	CERAMIC DIP (J)	CERAMIC DIP (JG)	PLASTIC DIP (N)	PLASTIC DIP (P)	
0°C to 70°C	TLC1078CD TLC1079CD	—	—	—	TLC1079CN	TLC1078CP	TLC1078Y TLC1079Y
–40°C to 85°C	TLC1078ID TLC1079ID	—	—	—	TLC1079IN	TLC1078IP	—
–55°C to 125°C	TLC1078MD TLC1079MD	TLC1078MFK TLC1079MFK	TLC1079MJ	TLC1078MJG	TLC1079MN	TLC1078MP	—

[†] The D package is available taped and reeled. Add the suffix R to the device type (e.g., TLC1078CDR).

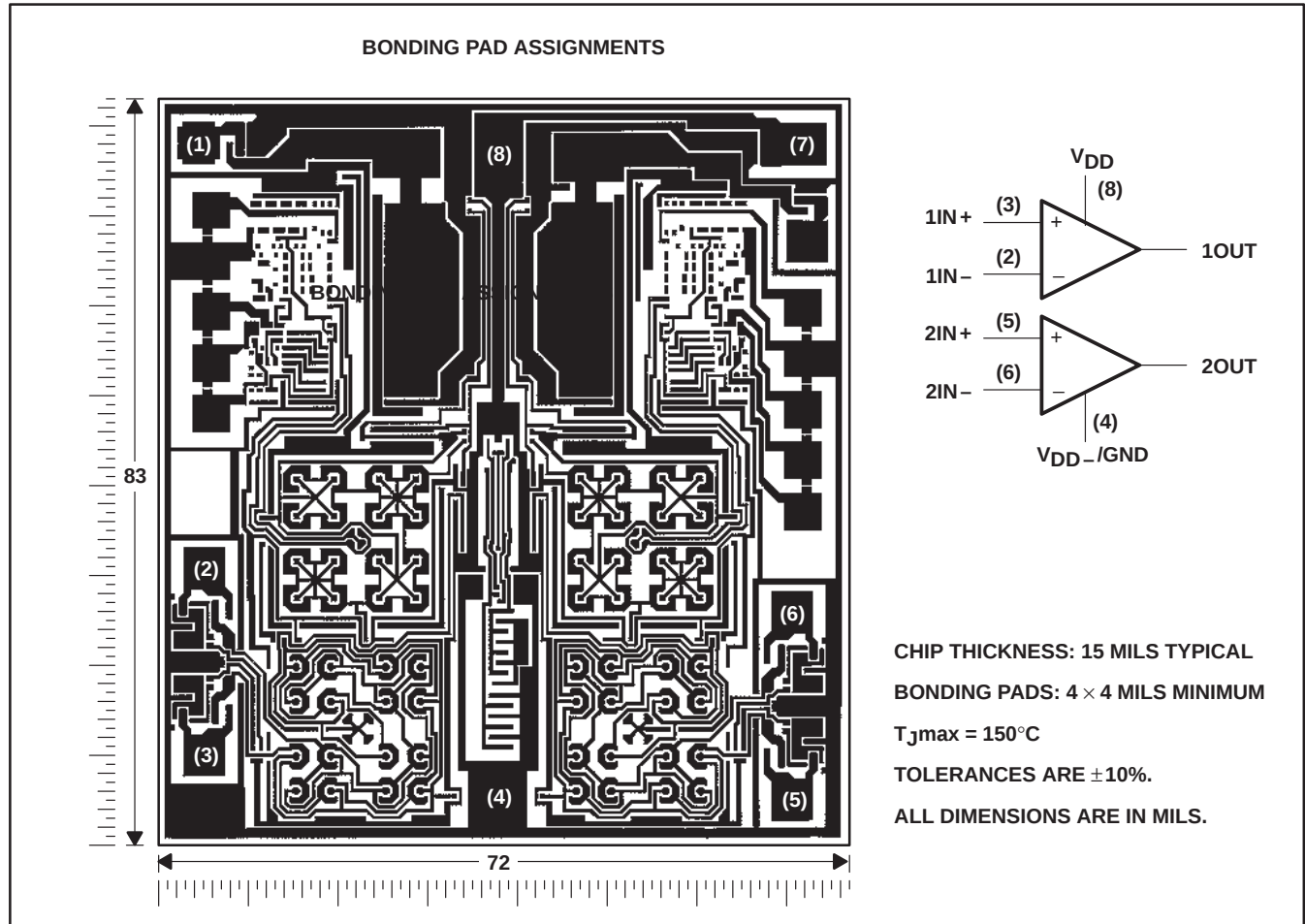
[‡] Chip forms are tested 25°C only.

symbol (each amplifier)



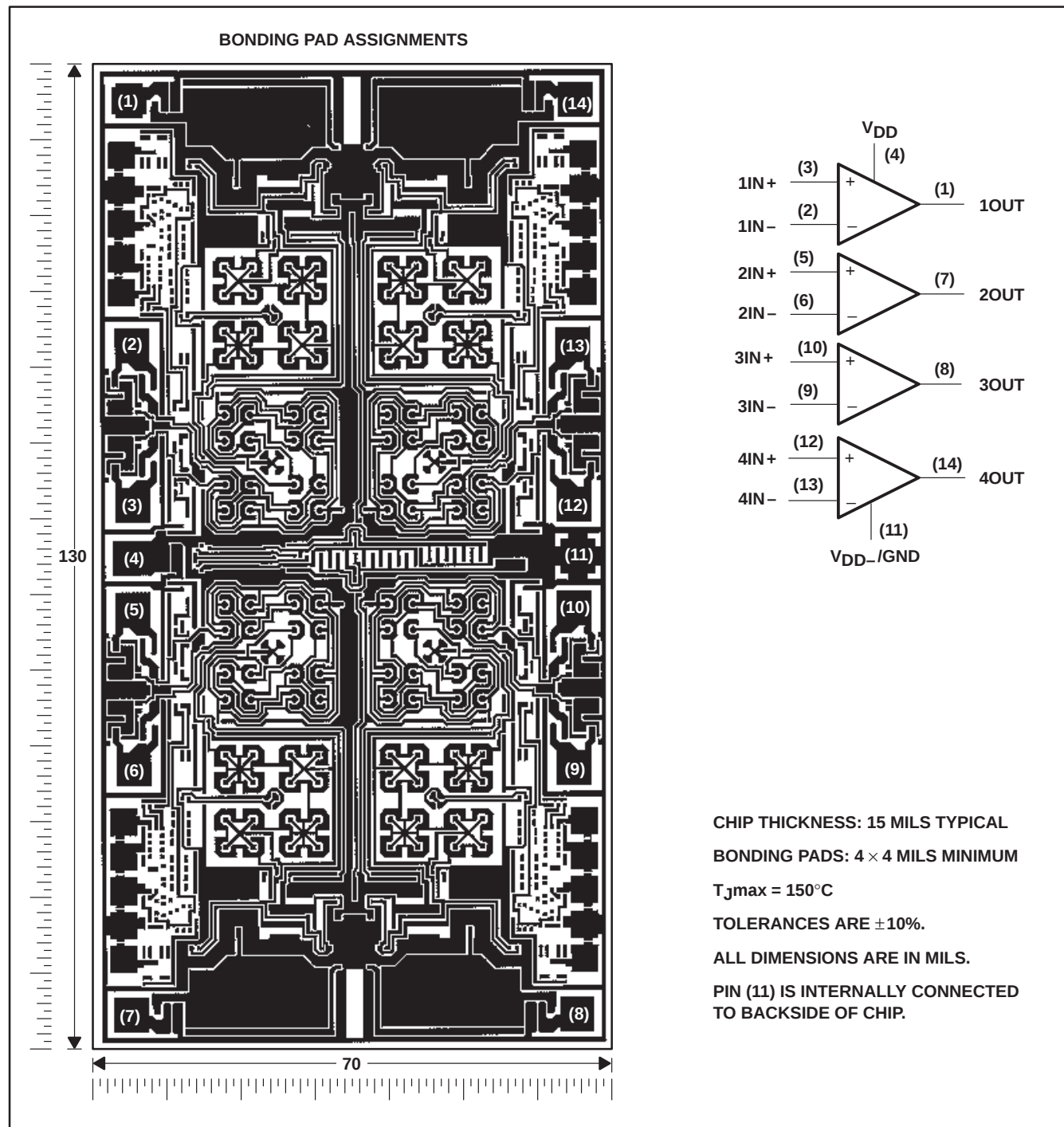
TLC1087Y chip information

This chip, when properly assembled, displays characteristics similar to the TLC1078C. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips can be mounted with conductive epoxy or a gold-silicon preform.

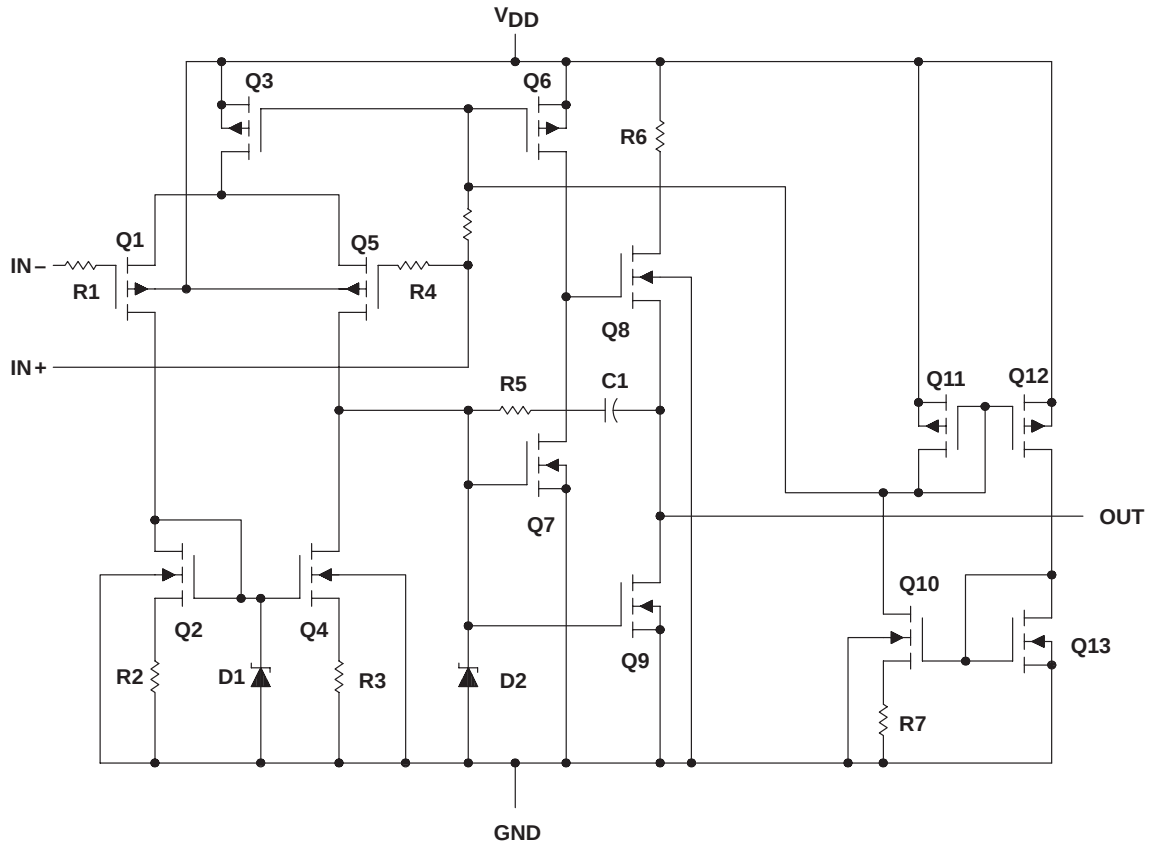


TLC1079Y chip information

This chip, when properly assembled, display characteristics similar to the TLC1079C. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips can be mounted with conductive epoxy or a gold-silicon preform.



equivalent schematic (each amplifier)



ACTUAL DEVICE COMPONENT COUNT		
COMPONENT	TLC1078	TLC1079
Transistors	38	76
Resistors	16	32
Diodes	12	24
Capacitors	2	4

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V_{DD} (see Note 1)	18 V
Differential input voltage, V_{ID} (see Note 2)	$\pm V_{DD}$
Input voltage range, V_I (any input)	–0.3 V to V_{DD}
Input current, I_I (each input)	± 5 mA
Output current, I_O (each output)	± 30 mA
Total current into V_{DD} (see Note 3)	45 mA
Duration of short-circuit at (or below) $T_A = 25^\circ\text{C}$ (see Note 3)	unlimited
Continuous total power dissipation	see Dissipation Rating Table
Operating free-air temperature range, T_A : C suffix	0°C to 70°C
I suffix	-40°C to 85°C
M suffix	-55°C to 125°C
Storage temperature range	-65°C to 150°C
Case temperature for 60 seconds: FK package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D or P package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: JG package	300°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential voltages, are with respect to network ground.
 2. Differential voltages are at $IN+$ with respect to $IN-$.
 3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation ratings are not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D–8	725 mW	5.8 mW/ $^\circ\text{C}$	464 mW	377 mW	145 mW
D–14	950 mW	7.6 mW/ $^\circ\text{C}$	608 mW	494 mW	190 mW
FK	1375 mW	11.0 mW/ $^\circ\text{C}$	880 mW	715 mW	275 mW
J	1375 mW	11.0 mW/ $^\circ\text{C}$	880 mW	715 mW	275 mW
JG	1050 mW	8.4 mW/ $^\circ\text{C}$	672 mW	546 mW	210 mW
N	1150 mW	9.2 mW/ $^\circ\text{C}$	736 mW	598 mW	230 mW
P	1000 mW	8.0 mW/ $^\circ\text{C}$	640 mW	520 mW	200 mW

recommended operating conditions

		C SUFFIX		I SUFFIX		M SUFFIX		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
Supply voltage, V_{DD}		1.4	16	3	16	4	16	V
Common-mode input voltage, V_{IC}	$V_{DD} = 5$ V	–0.2	4	–0.2	4	0	4	V
	$V_{DD} = 10$ V	–0.2	9	–0.2	9	0	9	
Operating free-air temperature, T_A		0	70	–40	85	–55	125	$^\circ\text{C}$

electrical characteristics at specified free-air temperature

PARAMETER		TEST CONDITIONS	T _A [†]	TLC1078C						UNIT
				V _{DD} = 5 V			V _{DD} = 10 V			
				MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	V _O = 1.4 V, R _S = 50 Ω, V _{IC} = 0, R _I = 1 MΩ	25°C	160 450		180 600		μV		
			Full range	800		950				
α _{VIO}	Temperature coefficient of input offset voltage		25°C to 70°C	1.1		1		μV/°C		
I _{IO}	Input offset current (see Note 4)	V _O = V _{DD} / 2, V _{IC} = V _{DD} / 2	25°C	0.1		0.1		pA		
			70°C	7	300	7	300			
I _{IB}	Input bias current (see Note 4)		25°C	0.6		0.7		pA		
			70°C	40	600	50	600			
V _{ICR}	Common-mode input voltage range (see Note 5)		25°C	−0.2 to 4	−0.3 to 4.2	−0.2 to 9	−0.3 to 9.2	V		
			Full range	−0.2 to 3.5		−0.2 to 8.5		V		
V _{OH}	High-level output voltage	V _{ID} = 100 mV, R _L = 1 MΩ	25°C	3.2	4.1	8.2	8.9	V		
			0°C	3.2	4.1	8.2	8.9			
			70°C	3.2	4.2	8.2	8.9			
V _{OL}	Low-level output voltage	V _{ID} = −100 mV, I _{OL} = 0	25°C	0 25		0 25		mV		
			0°C	0 25		0 25				
			70°C	0 25		0 25				
A _{VD}	Large-signal differential voltage amplification	R _L = 1 MΩ, See Note 6	25°C	250	525	500	850	V/mV		
			0°C	250	680	500	1010			
			70°C	200	380	350	660			
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICRmin}	25°C	70	95	75	97	dB		
			0°C	70	95	75	97			
			70°C	70	95	75	97			
k _{SVR}	Supply-voltage rejection ratio (ΔV _{DD} /ΔV _{IO})	V _O = 1.4 V	25°C	75	98	75	98	dB		
			0°C	75	98	75	98			
			70°C	75	98	75	98			
I _{DD}	Supply current (two amplifiers)	V _O = V _{DD} / 2, V _{IC} = V _{DD} / 2, No load	25°C	20	34	29	46	μA		
			0°C	24	42	36	66			
			70°C	16	28	22	40			

† Full range is 0°C to 70°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.

5. This range also applies to each input individually.

6. At $V_{DD} = 5\text{ V}$, $V_O = 0.25\text{ V}$ to 2 V ; at $V_{DD} = 10\text{ V}$, $V_O = 1\text{ V}$ to 6 V .

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electrical characteristics at specified free-air temperature

PARAMETER		TEST CONDITIONS	T _A [†]	TLC1079C						UNIT
				V _{DD} = 5 V			V _{DD} = 10 V			
				MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	V _O = 1.4 V, V _{IC} = 0, R _S = 50 Ω, R _I = 1 MΩ	25°C	190	850	200	1150	μV		
			Full range	1200			1500			
α _{VIO}	Temperature coefficient of input offset voltage		25°C to 70°C	1.1			1		μV/°C	
I _{IO}	Input offset current (see Note 4)	V _O = V _{DD} / 2, V _{IC} = V _{DD} / 2	25°C	0.1			0.1		pA	
			70°C	7	300	7	300			
I _{IB}	Input bias current (see Note 4)		25°C	0.6			0.7		pA	
			70°C	40	600	50	600			
V _{ICR}	Common mode input voltage range (see Note 5)		25°C	−0.2 to 4	−0.3 to 4.2	−0.2 to 9	−0.3 to 9.2	V		
			Full range	−0.2 to 3.5			−0.2 to 8.5		V	
V _{OH}	High-level output voltage	V _{ID} = 100 mV, R _L = 1 MΩ	25°C	3.2	4.1	8.2	8.9	V		
			0°C	3.2	4.1	8.2	8.9			
			70°C	3.2	4.2	8.2	8.9			
V _{OL}	Low-level output voltage	V _{ID} = −100 mV, I _{OL} = 0	25°C	0	25	0	25	mV		
			0°C	0	25	0	25			
			70°C	0	25	0	25			
A _{VD}	Large-signal differential voltage amplification	R _L = 1 MΩ, See Note 6	25°C	250	525	500	850	V/mV		
			0°C	250	700	500	1010			
			70°C	200	380	350	660			
CMRR	Common mode rejection ratio	V _{IC} = V _{ICRmin}	25°C	70	95	75	97	dB		
			0°C	70	95	75	97			
			70°C	70	95	75	97			
k _{SVR}	Supply-voltage rejection ratio (ΔV _{DD} /ΔV _{IO})	V _{DD} = 5 V to 10 V, V _O = 1.4 V	25°C	75	98	75	98	dB		
			0°C	75	98	75	98			
			70°C	75	98	75	98			
I _{DD}	Supply current (four amplifiers)	V _O = V _{DD} / 2, V _{IC} = V _{DD} / 2, No load	25°C	40	68	57	92	μA		
			0°C	48	84	72	132			
			70°C	31	56	44	80			

[†] Full range is 0°C to 70°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.

5. This range also applies to each input individually.

6. At $V_{DD} = 5\text{ V}$, $V_O = 0.25\text{ V to }2\text{ V}$; at $V_{DD} = 10\text{ V}$, $V_O = 1\text{ V to }6\text{ V}$.

operating characteristics at specified free-air temperature

PARAMETER		TEST CONDITIONS		T _A	TLC1078C						UNIT
					V _{DD} = 5 V			V _{DD} = 10 V			
					MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	R _L = 1 MΩ, V _{I(PP)} = 1 V, See Figure 1	C _L = 20 pF, See Figure 1	25°C	32			47			V/ms
				0°C	35			51			
				70°C	27			38			
V _n	Equivalent input noise voltage	f = 1 kHz,	R _S = 20 Ω	25°C	68			68			nV/√Hz
B ₁	Unity-gain bandwidth	C _L = 20 pF,	See Figure 2	25°C	85			110			kHz
				0°C	100			125			
				70°C	65			90			
φ _m	Phase margin at unity gain	C _L = 20 pF,	See Figure 2	25°C	34°			38°			
				0°C	36°			40°			
				70°C	30°			34°			

operating characteristics at specified free-air temperature

PARAMETER		TEST CONDITIONS		T _A	TLC1079C						UNIT
					V _{DD} = 5 V			V _{DD} = 10 V			
					MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	R _L = 1 MΩ, V _{I(PP)} = 1 V, See Figure 1	C _L = 20 pF, See Figure 1	25°C	32			47			V/ms
				0°C	35			51			
				70°C	27			38			
V _n	Equivalent input noise voltage	f = 1 kHz,	R _S = 20 Ω	25°C	68			68			nV/√Hz
B ₁	Unity-gain bandwidth	C _L = 20 pF,	See Figure 2	25°C	85			110			kHz
				0°C	100			125			
				70°C	65			90			
φ _m	Phase margin at unity gain	C _L = 20 pF,	See Figure 2	25°C	34°			38°			
				0°C	36°			40°			
				70°C	30°			34°			

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electrical characteristics at specified free-air temperature

PARAMETER		TEST CONDITIONS	T _A [†]	TLC1078I						UNIT
				V _{DD} = 5 V			V _{DD} = 10 V			
				MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	V _O = 1.4 V, R _S = 50 Ω, V _{IC} = 0, R _I = 1 MΩ	25°C	160		450	180		600	μV
			Full range			950			1100	
α _{VIO}	Temperature coefficient of input offset voltage		25°C to 85°C	1.1			1			μV/°C
I _{IO}	Input offset current (see Note 4)	V _O = V _{DD} / 2, V _{IC} = V _{DD} / 2	25°C	0.1			0.1			pA
			85°C	24		1000	26		1000	
I _{IB}	Input bias current (see Note 4)		25°C	0.6			0.7			pA
			85°C	200		2000	220		2000	
V _{ICR}	Common-mode input voltage range (see Note 5)		25°C	−0.2 to 4	−0.3 to 4.2		−0.2 to 9	−0.3 to 9.2		V
			Full range	−0.2 to 3.5			−0.2 to 8.5			V
V _{OH}	High-level output voltage	V _{ID} = 100 mV, R _L = 1 MΩ	25°C	3.2	4.1		8.2	8.9		V
			−40°C	3.2	4.1		8.2	8.9		
			85°C	3.2	4.2		8.2	8.9		
V _{OL}	Low-level output voltage	V _{ID} = −100 mV, I _{OL} = 0	25°C	0		25	0		25	mV
			−40°C	0		25	0		25	
			85°C	0		25	0		25	
A _{VD}	Large-signal differential voltage amplification	R _L = 1 MΩ, See Note 6	25°C	250	525		500	850		V/mV
			−40°C	250	900		500	1550		
			85°C	150	300		250	585		
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICRmin}	25°C	70	95		75	97		dB
			−40°C	70	95		75	97		
			85°C	70	95		75	97		
k _{SVR}	Supply-voltage rejection ratio (ΔV _{DD} /ΔV _{IO})	V _O = 1.4 V	25°C	75	98		75	98		dB
			−40°C	75	98		75	98		
			85°C	75	98		75	98		
I _{DD}	Supply current (two amplifiers)	V _O = V _{DD} / 2, V _{IC} = V _{DD} / 2, No load	25°C	20		34	29		46	μA
			−40°C	31		54	50		86	
			85°C	15		26	20		36	

† Full range is –40°C to 80°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.

5. This range also applies to each input individually.

6. At $V_{DD} = 5\text{ V}$, $V_O = 0.25\text{ V}$ to 2 V ; at $V_{DD} = 10\text{ V}$, $V_O = 1\text{ V}$ to 6 V .



electrical characteristics at specified free-air temperature

PARAMETER		TEST CONDITIONS	T _A [†]	TLC1079I						UNIT
				V _{DD} = 5 V			V _{DD} = 10 V			
				MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	V _O = 1.4 V, V _{IC} = 0, R _S = 50 Ω, R _I = 1 MΩ	25°C	190	850	200	1150	μV		
			Full range	1350			1650			
α _{VIO}	Temperature coefficient of input offset voltage		25°C to 85°C	1.1		1		μV/°C		
I _{IO}	Input offset current (see Note 4)	V _O = V _{DD} / 2, V _{IC} = V _{DD} / 2	25°C	0.1		0.1		pA		
			85°C	24	1000	26	1000			
I _{IB}	Input bias current (see Note 4)		25°C	0.6		0.7		pA		
			85°C	200	2000	220	2000			
V _{ICR}	Common-mode input voltage range (see Note 5)		25°C	-0.2 to 4	-0.3 to 4.2	-0.2 to 9	-0.3 to 9.2	V		
			Full range	-0.2 to 3.5		-0.2 to 8.5		V		
V _{OH}	High-level output voltage	V _{ID} = 100 mV, R _L = 1 MΩ	25°C	3.2	4.1	8.2	8.9	V		
			-40°C	3.2	4.1	8.2	8.9			
			85°C	3.2	4.2	8.2	8.9			
V _{OL}	Low-level output voltage	V _{ID} = -100 mV, I _{OL} = 0	25°C	0	25	0	25	mV		
			-40°C	0	25	0	25			
			85°C	0	25	0	25			
A _{VD}	Large-signal differential voltage amplification	R _L = 1 MΩ, See Note 6	25°C	250	525	500	850	V/mV		
			-40°C	250	900	500	1550			
			85°C	150	330	250	585			
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICR} min	25°C	70	95	75	97	dB		
			-40°C	70	95	75	97			
			85°C	70	95	75	97			
k _{SVR}	Supply-voltage rejection ratio (ΔV _{DD} /ΔV _{IO})	V _{DD} = 5 V to 10 V, V _O = 1.4 V	25°C	75	98	75	98	dB		
			-40°C	75	98	75	98			
			85°C	75	98	75	98			
I _{DD}	Supply current (four amplifiers)	V _O = V _{DD} / 2, V _{IC} = V _{DD} / 2, No load	25°C	40	68	57	92	μA		
			-40°C	62	108	98	172			
			85°C	29	52	40	72			

† Full range is -40°C to 85°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.

5. This range also applies to each input individually.

6. At $V_{DD} = 5\text{ V}$, $V_O = 0.25\text{ V to }2\text{ V}$; at $V_{DD} = 10\text{ V}$, $V_O = 1\text{ V to }6\text{ V}$.

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operating characteristics at specified free-air temperature

PARAMETER	TEST CONDITIONS	T _A	TLC1078I						UNIT
			V _{DD} = 5 V			V _{DD} = 10 V			
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	R _L = 1 MΩ, C _L = 20 pF, V _{I(PP)} = 1 V, See Figure 1	25°C	32			47			V/ms
		−40°C	39			59			
		85°C	25			34			
V _n Equivalent input noise voltage	f = 1 kHz, R _S = 20 Ω	25°C	68			68			nV/√Hz
B ₁ Unity-gain bandwidth	C _L = 20 pF, See Figure 2	25°C	85			110			kHz
		−40°C	130			155			
		85°C	55			80			
ϕ _m Phase margin at unity gain	C _L = 20 pF, See Figure 2	25°C	34°			38°			
		−40°C	38°			40°			
		85°C	28°			32°			

operating characteristics at specified free-air temperature

PARAMETER	TEST CONDITIONS	T _A	TLC1079I						UNIT
			V _{DD} = 5 V			V _{DD} = 10 V			
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	R _L = 1 MΩ, C _L = 20 pF, V _{I(PP)} = 1 V, See Figure 1	25°C	32			47			V/ms
		−40°C	39			59			
		85°C	25			34			
V _n Equivalent input noise voltage	f = 1 kHz, R _S = 20 Ω	25°C	68			68			nV/√Hz
B ₁ Unity-gain bandwidth	C _L = 20 pF, See Figure 2	25°C	85			110			kHz
		−40°C	130			155			
		85°C	55			80			
ϕ _m Phase margin at unity gain	C _L = 20 pF, See Figure 2	25°C	34°			38°			
		−40°C	38°			42°			
		85°C	28°			32°			



electrical characteristics at specified operating free-air temperature

PARAMETER		TEST CONDITIONS	T _A [†]	TLC1078M						UNIT
				V _{DD} = 5 V			V _{DD} = 10 V			
				MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	V _O = 1.4 V, V _{IC} = 0, R _S = 50 Ω, R _L = 1 MΩ	25°C	160	450	180	600			μV
			Full range	1250		1400				
α _{VIO}	Temperature coefficient of input offset voltage		25°C to 125°C	1.4		1.4				μV/°C
I _{IO}	Input offset current (see Note 4)	V _O = V _{DD} / 2, V _{IC} = V _{DD} / 2	25°C	0.1		0.1				pA
			125°C	1.4	15	1.8	15			nA
I _{IB}	Input bias current (see Note 4)		25°C	0.6		0.7				pA
			125°C	9	35	10	35			nA
V _{ICR}	Common-mode input voltage range (see Note 5)		25°C	0 to 4	−0.3 to 4.2	0 to 9	−0.3 to 9.2			V
			Full range	0 to 3.5		0 to 8.5				V
V _{OH}	High-level output voltage	V _{ID} = 100 mV, R _L = 1 MΩ	25°C	3.2	4.1	8.2	8.9			V
			−55°C	3.2	4.1	8.2	8.8			
			125°C	3.2	4.2	8.2	9			
V _{OL}	Low-level output voltage	V _{ID} = −100 mV, I _{OL} = 0	25°C	0 25		0 25				mV
			−55°C	0 25		0 25				
			125°C	0 25		0 25				
A _{VD}	Large-signal differential voltage amplification	R _L = 1 MΩ , See Note 6	25°C	250	525	500	850			V/mV
			−55°C	250	950	500	1750			
			125°C	35	200	75	380			
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICRmin}	25°C	70	95	75	97			dB
			−55°C	70	95	75	97			
			125°C	70	85	75	91			
k _{SVR}	Supply-voltage rejection ratio (ΔV _{DD} /ΔV _{IO})	V _O = 1.4 V	25°C	75	98	75	98			dB
			−55°C	70	98	70	98			
			125°C	70	98	70	98			
I _{DD}	Supply current (two amplifiers)	V _O = V _{DD} / 2, V _{IC} = V _{DD} / 2, No load	25°C	20	34	29	46			μA
			−55°C	35	60	56	96			
			125°C	14	24	18	30			

† Full range is –55°C to 125°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.

5. This range also applies to each input individually.

6. At $V_{DD} = 5\text{ V}$, $V_O = 0.25\text{ V}$ to 2 V ; at $V_{DD} = 10\text{ V}$, $V_O = 1\text{ V}$ to 6 V .

TLC1078, TLC1078Y, TLC1079, TLC1079Y
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OPERATIONAL AMPLIFIERS

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electrical characteristics at specified free-air temperature

PARAMETER		TEST CONDITIONS	T _A [†]	TLC1079M						UNIT
				V _{DD} = 5 V			V _{DD} = 10 V			
				MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	V _O = 1.4 V, V _{IC} = 0, R _S = 50 Ω, R _I = 1 MΩ	25°C	190	850	200	1150	μV		
			Full range	1600		1900				
α _{VIO}	Temperature coefficient of input offset voltage		25°C to 125°C	1.4		1.4		μV/°C		
I _{IO}	Input offset current (see Note 4)	V _O = V _{DD} / 2, V _{IC} = V _{DD} / 2	25°C	0.1		0.1		pA		
			125°C	1.4	15	1.8	15	nA		
I _{IB}	Input bias current (see Note 4)		25°C	0.6		0.7		pA		
			125°C	9	35	10	35	nA		
V _{ICR}	Common mode input voltage range (see Note 5)		25°C	0 to 4	–0.3 to 4.2	0 to 9	–0.3 to 9.2	V		
			Full range	0 to 3.5		0 to 8.5		V		
V _{OH}	High-level output voltage	V _{ID} = 100 mV, R _L = 1 MΩ	25°C	3.2	4.1	8.2	8.9	V		
			–55°C	3.2	4.1	8.2	8.9			
			125°C	3.2	4.2	8.2	9			
V _{OL}	Low-level output voltage	V _{ID} = –100 mV, I _{OL} = 0	25°C	0	25	0	25	mV		
			–55°C	0	25	0	25			
			125°C	0	25	0	25			
A _{VD}	Large-signal differential voltage amplification	R _L = 1 MΩ, See Note 6	25°C	250	525	500	850	V/mV		
			–55°C	250	950	500	1750			
			125°C	35	200	75	380			
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICRmin}	25°C	70	95	75	97	dB		
			–55°C	70	95	75	97			
			125°C	70	85	75	91			
k _{SVR}	Supply voltage rejection ratio (ΔV _{DD} /ΔV _{IO})	V _{DD} = 5 V to 10 V, V _O = 1.4 V	25°C	75	98	75	98	dB		
			–55°C	70	98	70	98			
			125°C	70	98	70	98			
I _{DD}	Supply current (four amplifiers)	V _O = V _{DD} / 2, V _{IC} = V _{DD} / 2, No load	25°C	40	68	57	92	μA		
			–55°C	69	120	111	192			
			125°C	27	48	35	60			

[†] Full range is –55°C to 125°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.

5. This range also applies to each input individually.

6. At $V_{DD} = 5\text{ V}$, $V_O = 0.25\text{ V to }2\text{ V}$; at $V_{DD} = 10\text{ V}$, $V_O = 1\text{ V to }6\text{ V}$.



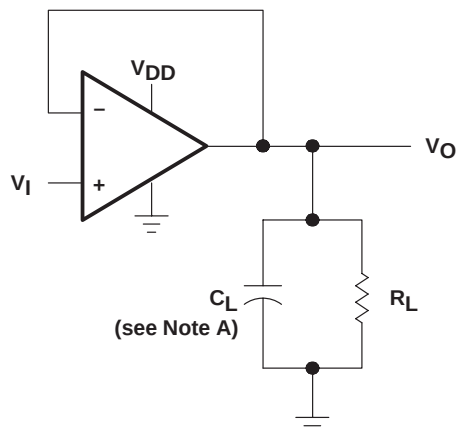
operating characteristics at specified free-air temperature

PARAMETER		TEST CONDITIONS		T _A	TLC1078M						UNIT
					V _{DD} = 5 V			V _{DD} = 10 V			
					MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	R _L = 1 MΩ, C _L = 20 pF, V _{I(PP)} = 1 V, See Figure 1	25°C	32			47			V/ms	
			–55°C	41			63				
			125°C	20			27				
V _n	Equivalent input noise voltage	f = 1 kHz, R _S = 20 Ω	25°C	68			68			nV/√Hz	
B ₁	Unity-gain bandwidth	C _L = 20 pF, See Figure 2	25°C	85			110			kHz	
			–55°C	140			165				
			125°C	45			70				
φ _m	Phase margin at unity gain	C _L = 20 pF, See Figure 2	25°C	34°			38°				
			–55°C	39°			43°				
			125°C	25°			29°				

operating characteristics at specified free-air temperature

PARAMETER	TEST CONDITIONS	T _A	TLC1079M						UNIT
			V _{DD} = 5 V			V _{DD} = 10 V			
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	R _L = 1 MΩ, C _L = 20 pF, V _{I(PP)} = 1 V, See Figure 1	25°C	32			47			V/ms
		–55°C	41			63			
		125°C	20			27			
V _n Equivalent input noise voltage	f = 1 kHz, R _S = 20 Ω	25°C	68			68			nV/√Hz
B ₁ Unity-gain bandwidth	C _L = 20 pF, See Figure 2	25°C	85			110			kHz
		–55°C	140			165			
		125°C	45			70			
ϕ _m Phase margin at unity gain	C _L = 20 pF, See Figure 2	25°C	34°			38°			
		–55°C	39°			43°			
		125°C	25°			29°			

PARAMETER MEASUREMENT INFORMATION



NOTE A: C_L includes fixture capacitance.

Figure 1. Slew-Rate Test Circuit

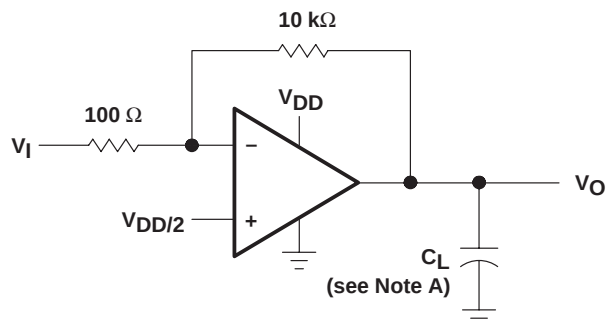


Figure 2. Unity-Gain Bandwidth and Phase-Margin Test Circuit

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
α_{VIO}	Temperature coefficient of input offset voltage	Distribution	3 – 6
I_{IB}	Input bias current	vs Free-air temperature	7
I_{IO}	Input offset current	vs Free-air temperature	7
V_{IC}	Common-mode input voltage	vs Supply voltage	8
V_{OH}	High-level output voltage	vs High-level output current vs Supply voltage vs Free-air temperature	9, 10 11 12
V_{OL}	Low-level output voltage	vs Common-mode input voltage vs Differential input voltage vs Free-air temperature vs Low-level output current	13, 14 15 16 17, 18
A_{VD}	Large-signal differential voltage amplification	vs Supply voltage vs Free-air temperature vs Frequency	19 20 21, 22
V_{OM}	Maximum peak output voltage	vs Frequency	23
I_{DD}	Supply current	vs Supply voltage vs Free-air temperature	24 25
SR	Slew rate	vs Supply voltage vs Free-air temperature	26 27
	Normalized slew rate	vs Free-air temperature	28
V_n	Equivalent input noise voltage	vs Frequency	29
B_1	Unity-gain bandwidth	vs Supply voltage vs Free-air temperature	30 31
ϕ_m	Phase margin	vs Supply voltage vs Free-air temperature vs Capacitance load	32 33 34
	Phase shift	vs Frequency	21, 22

TYPICAL CHARACTERISTICS

DISTRIBUTION OF TLC1078
 INPUT OFFSET VOLTAGE
 TEMPERATURE COEFFICIENT

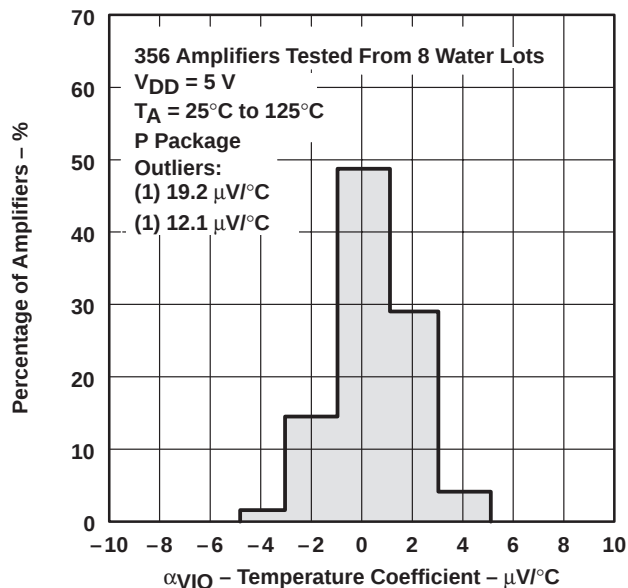


Figure 3

DISTRIBUTION OF TLC1078
 INPUT OFFSET VOLTAGE
 TEMPERATURE COEFFICIENT

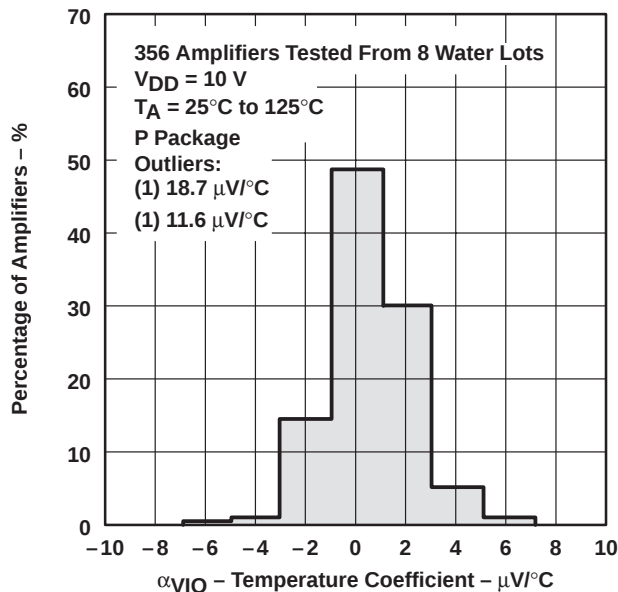


Figure 4

DISTRIBUTION OF TLC1079
 INPUT OFFSET VOLTAGE
 TEMPERATURE COEFFICIENT

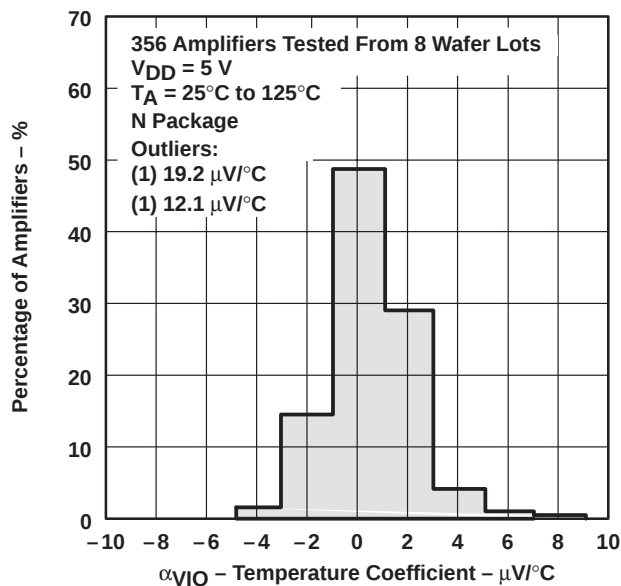


Figure 5

DISTRIBUTION OF TLC1079
 INPUT OFFSET VOLTAGE
 TEMPERATURE COEFFICIENT

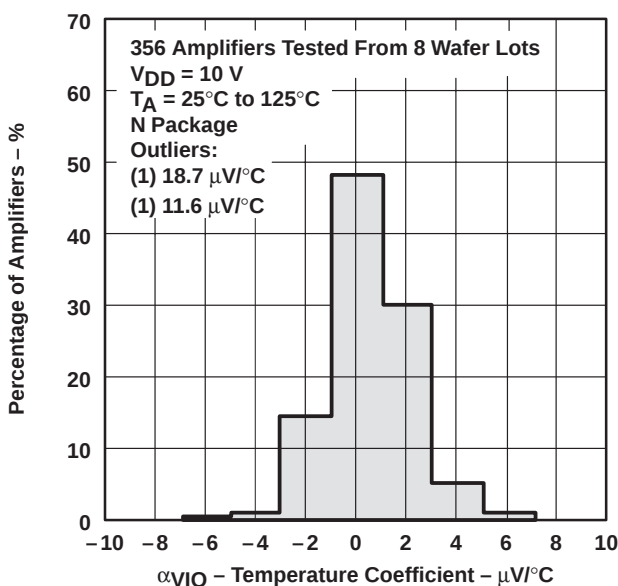
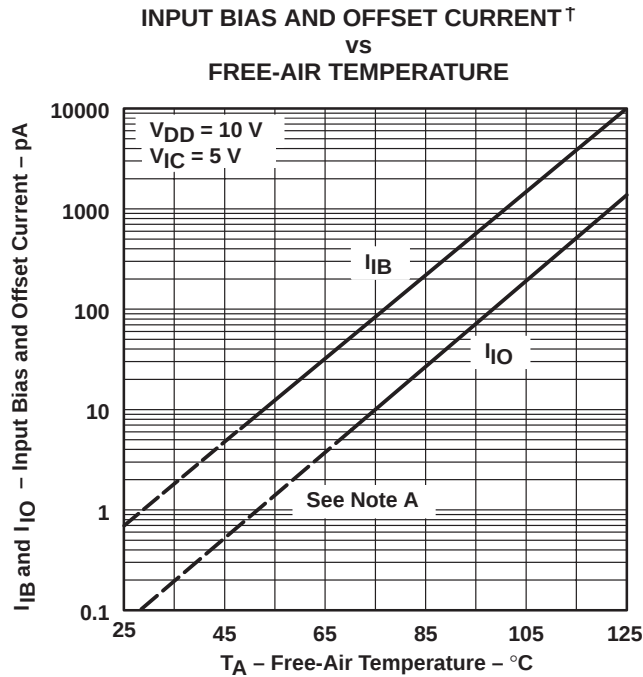


Figure 6

TYPICAL CHARACTERISTICS



NOTE A: The typical values of input bias current and input offset current below 5 pA were determined mathematically.

Figure 7

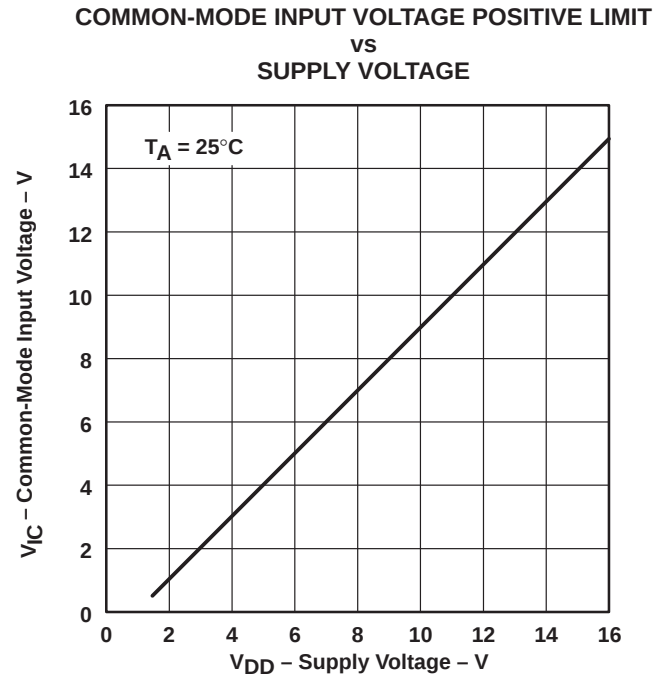


Figure 8

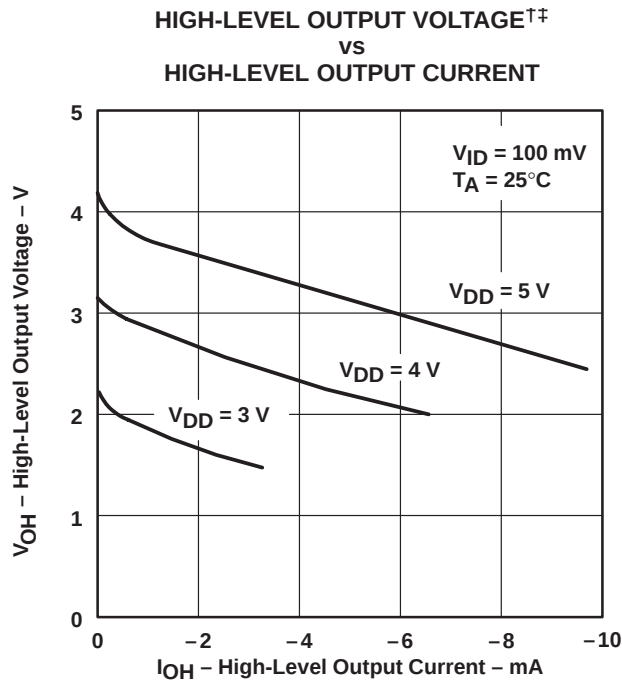


Figure 9

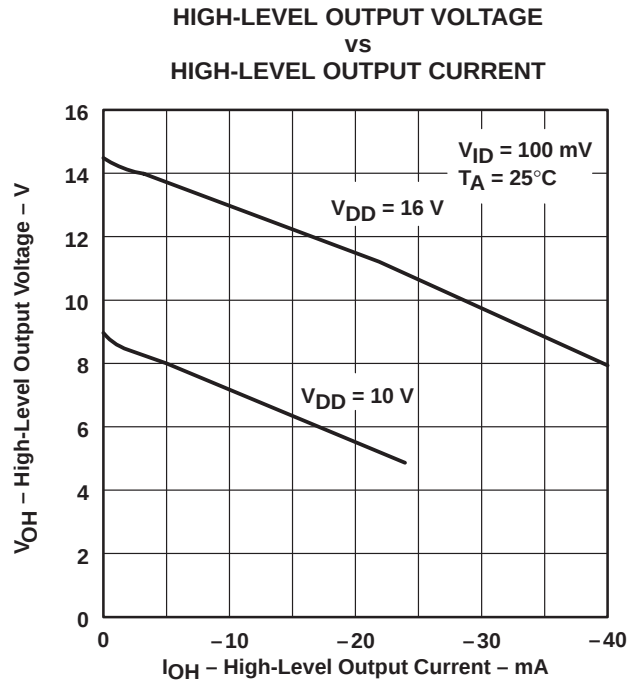


Figure 10

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

[‡] The $V_{DD} = 3\text{ V}$ curve does not apply to the TLC107xM.

TYPICAL CHARACTERISTICS

HIGH-LEVEL OUTPUT VOLTAGE
 vs
 SUPPLY VOLTAGE

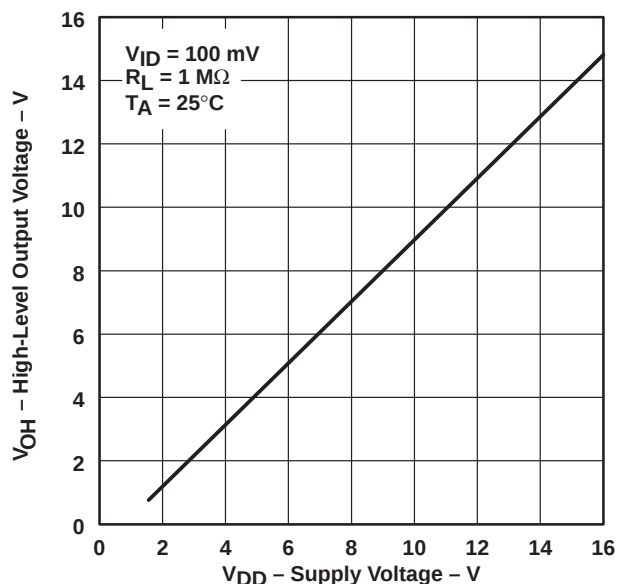


Figure 11

HIGH-LEVEL OUTPUT VOLTAGE†
 vs
 FREE-AIR TEMPERATURE

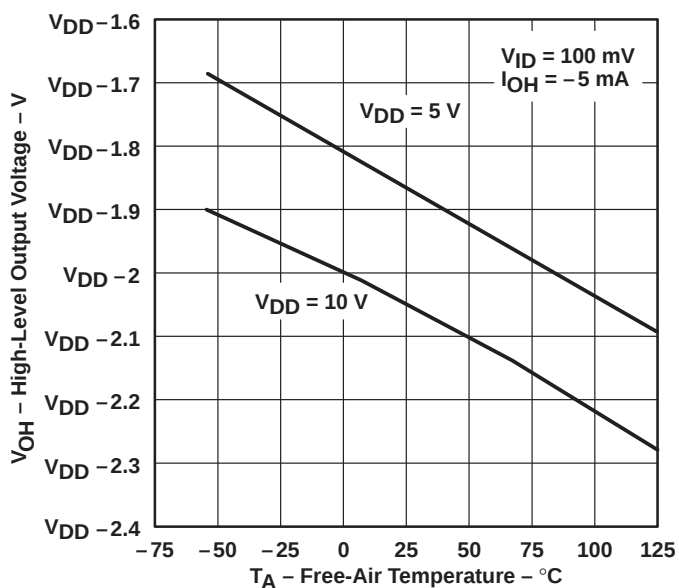


Figure 12

LOW-LEVEL OUTPUT VOLTAGE
 vs
 COMMON-MODE INPUT VOLTAGE

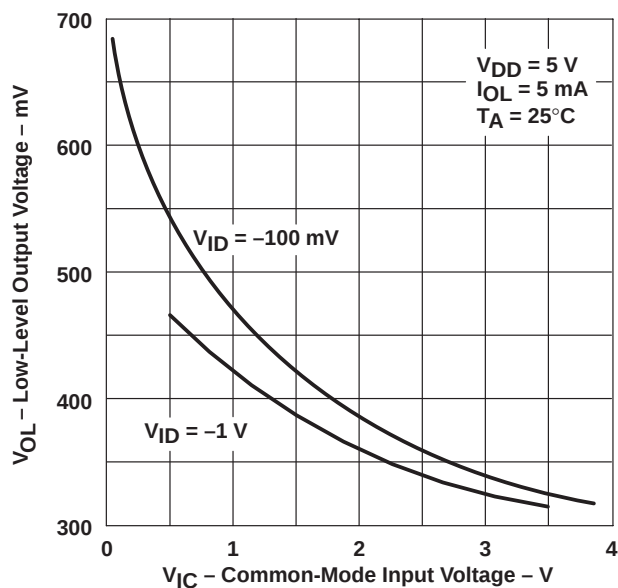


Figure 13

LOW-LEVEL OUTPUT VOLTAGE
 vs
 COMMON-MODE INPUT VOLTAGE

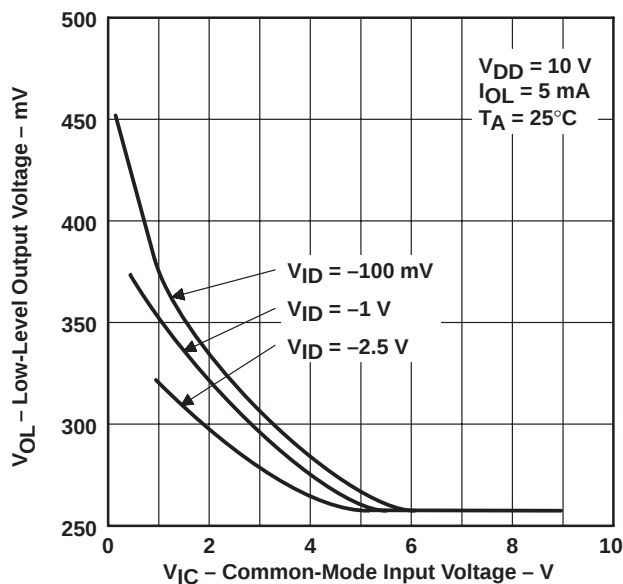


Figure 14

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

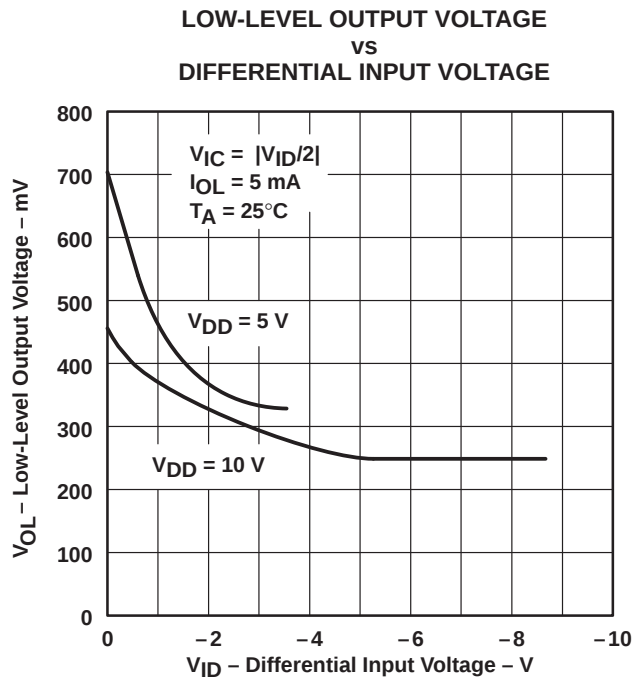


Figure 15

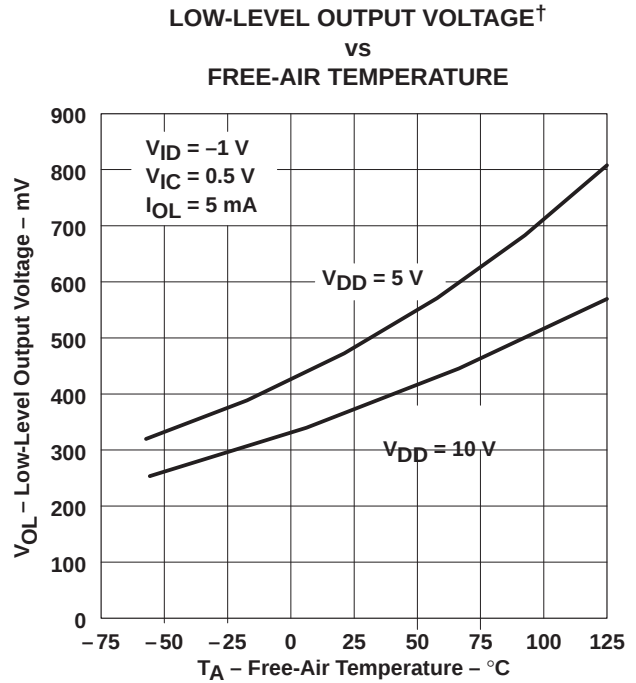


Figure 16

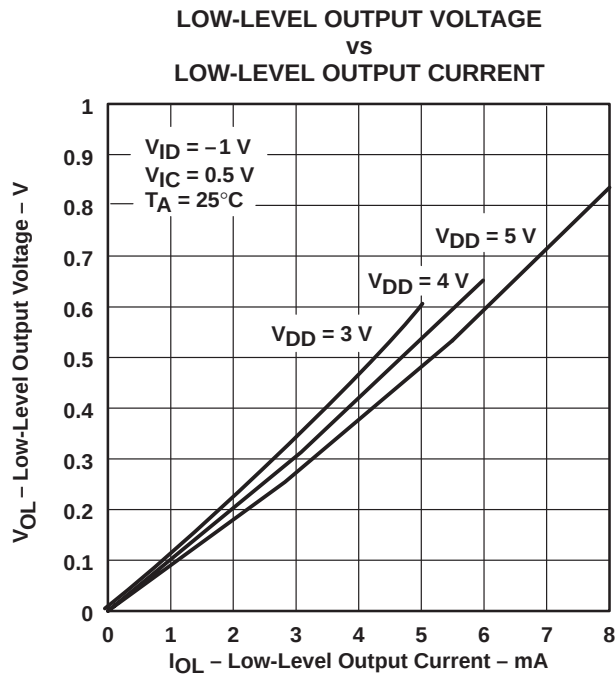


Figure 17

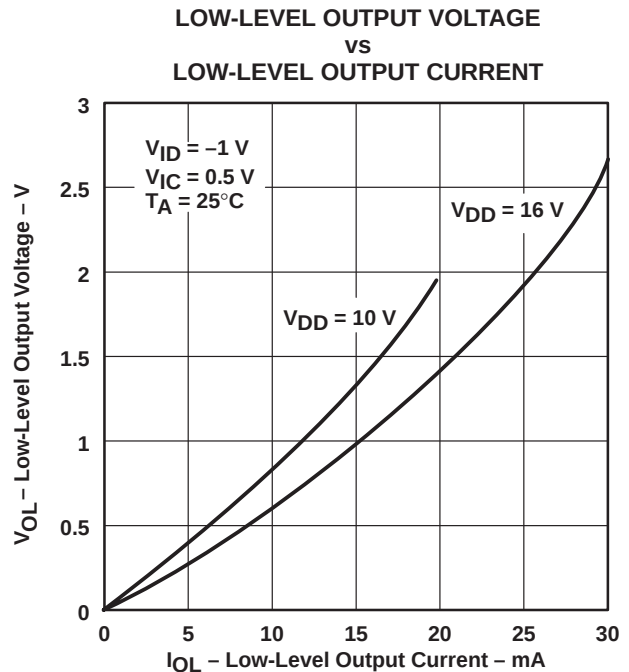


Figure 18

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

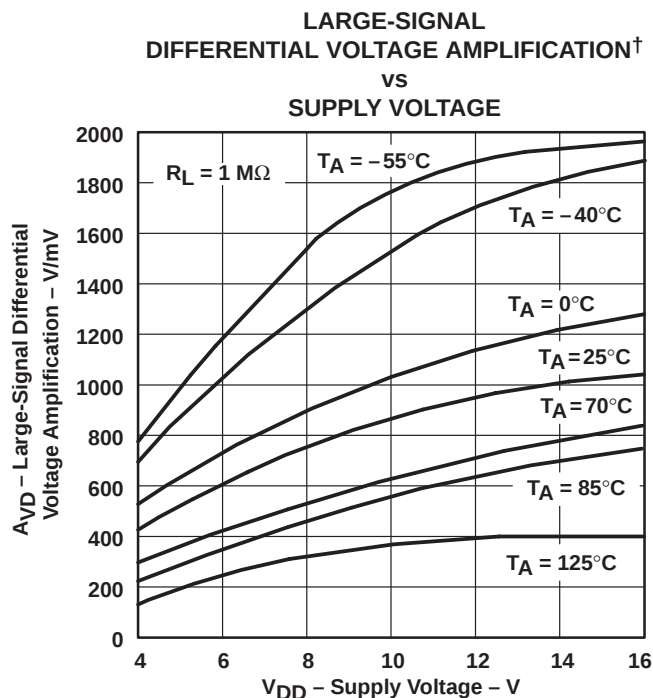


Figure 19

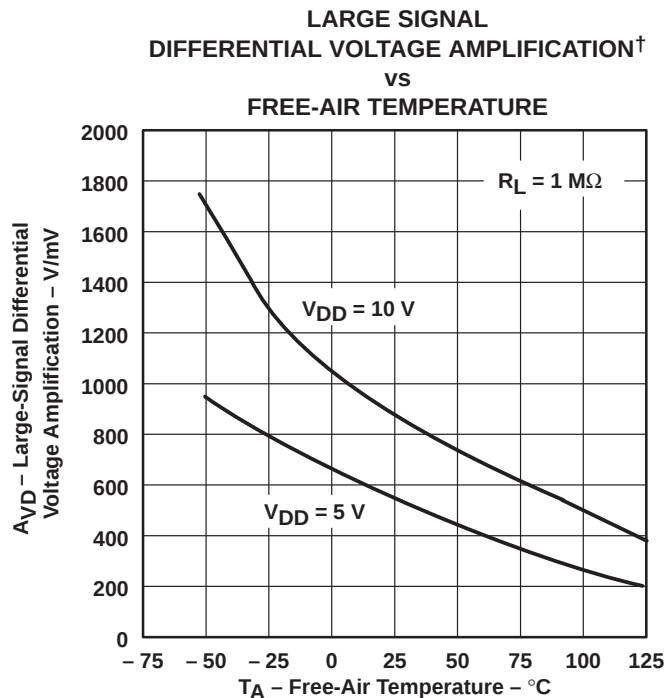


Figure 20

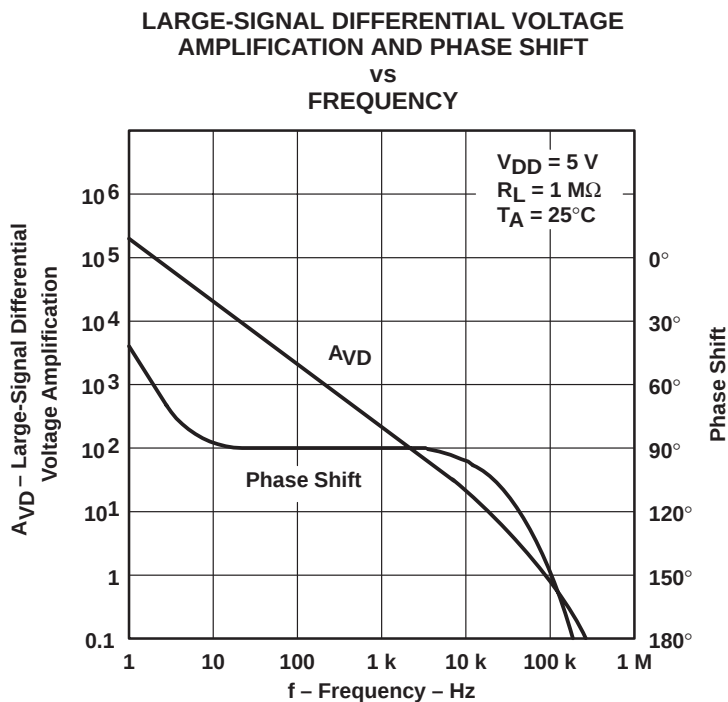


Figure 21

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT VS FREQUENCY

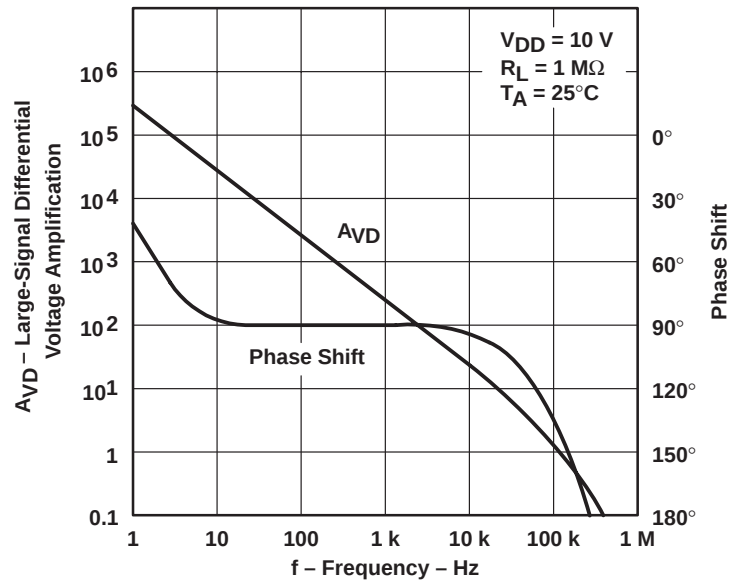


Figure 22

MAXIMUM PEAK OUTPUT VOLTAGE VS FREQUENCY

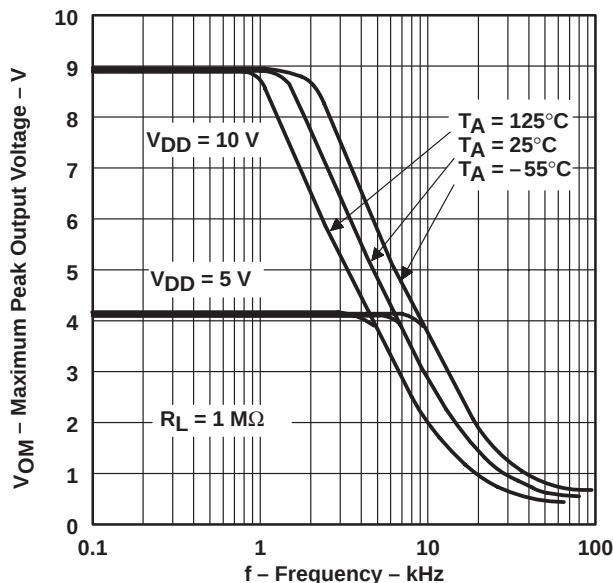


Figure 23

SUPPLY CURRENT† VS SUPPLY VOLTAGE

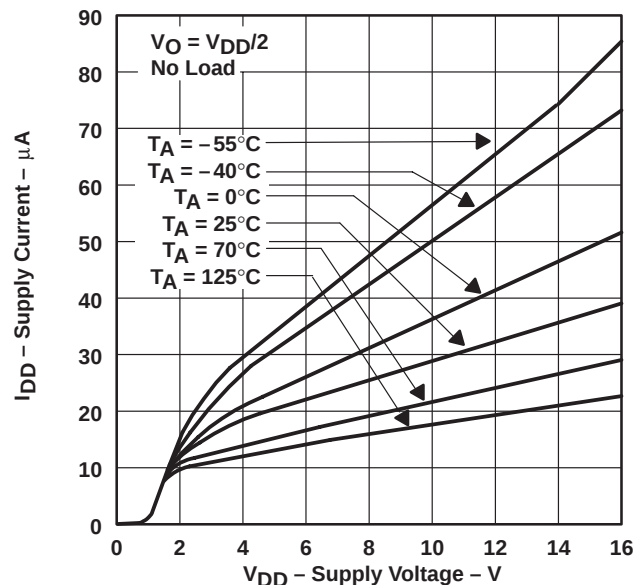
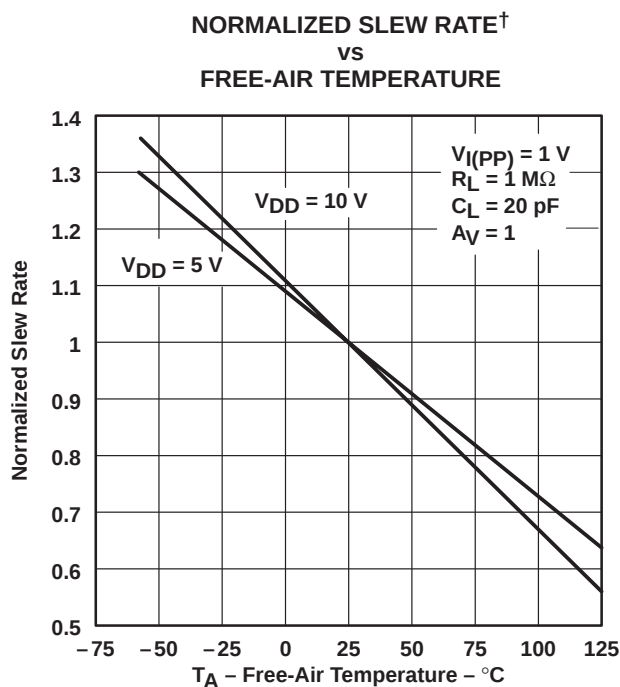
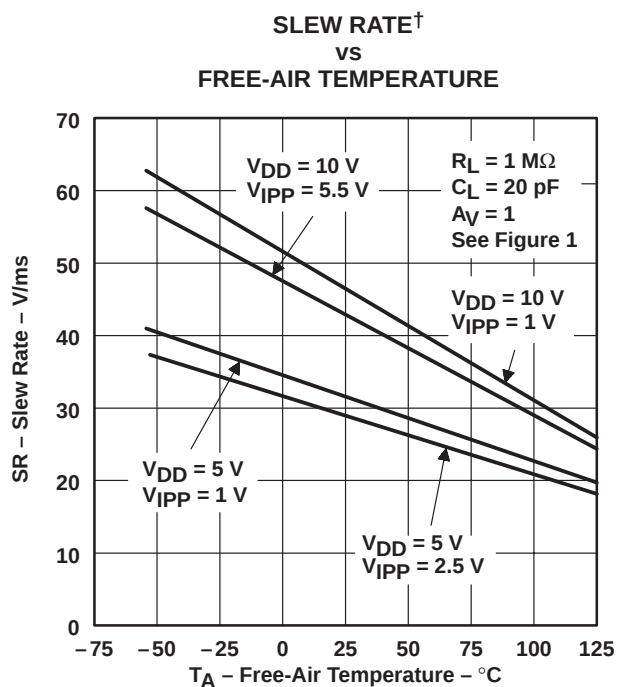
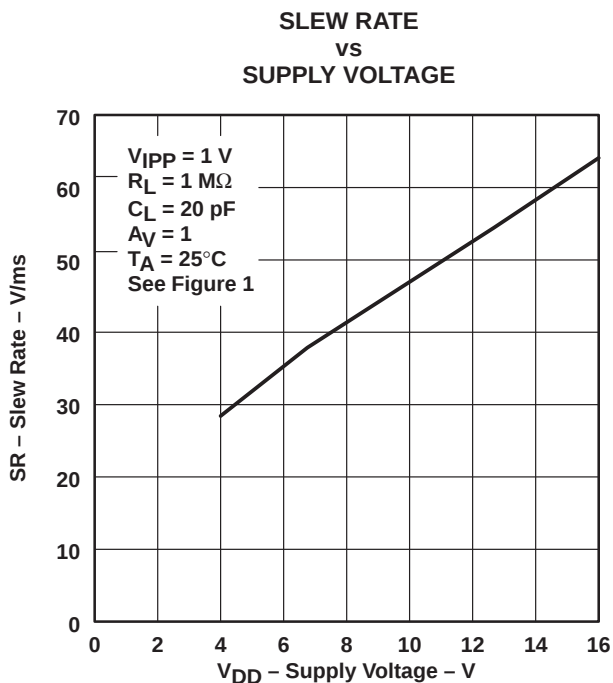
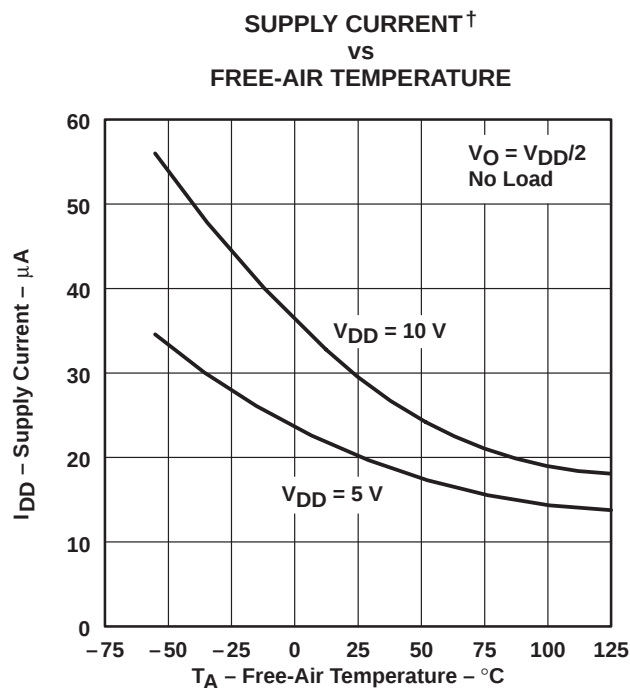


Figure 24

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS



[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

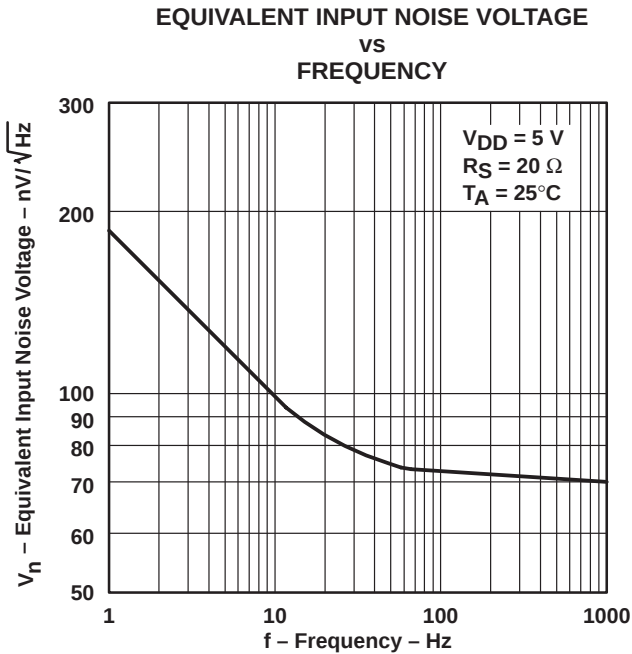


Figure 29

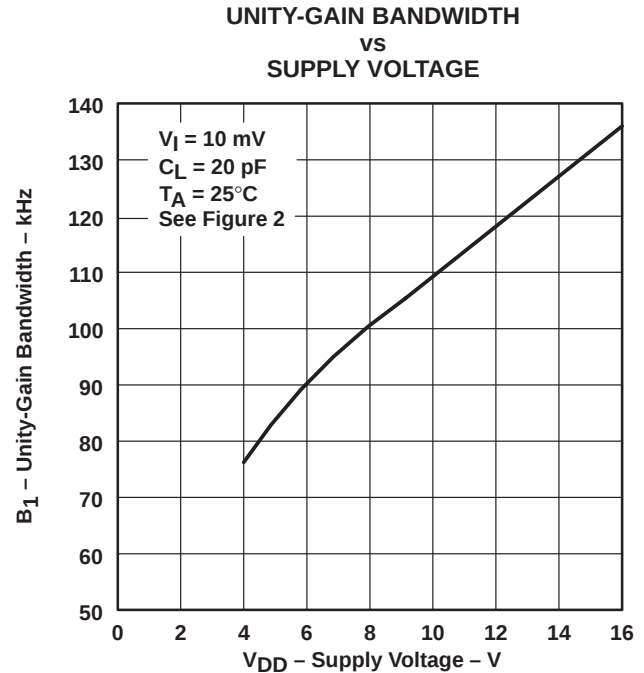


Figure 30

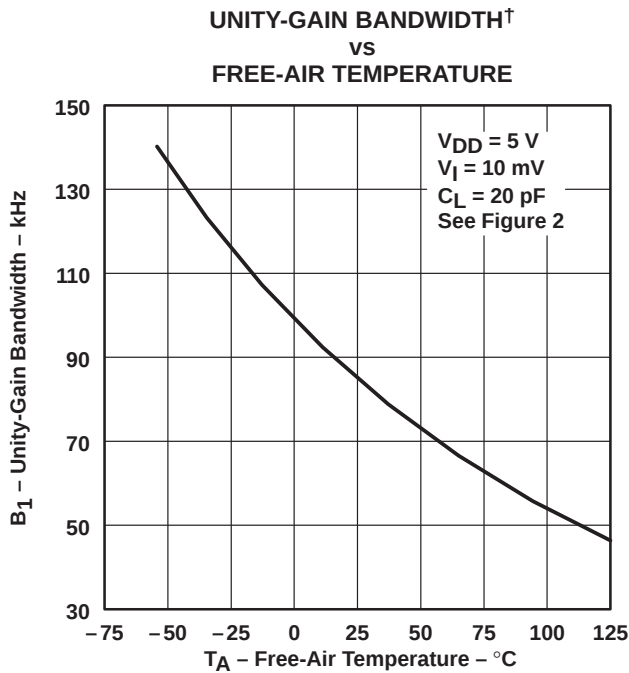


Figure 31

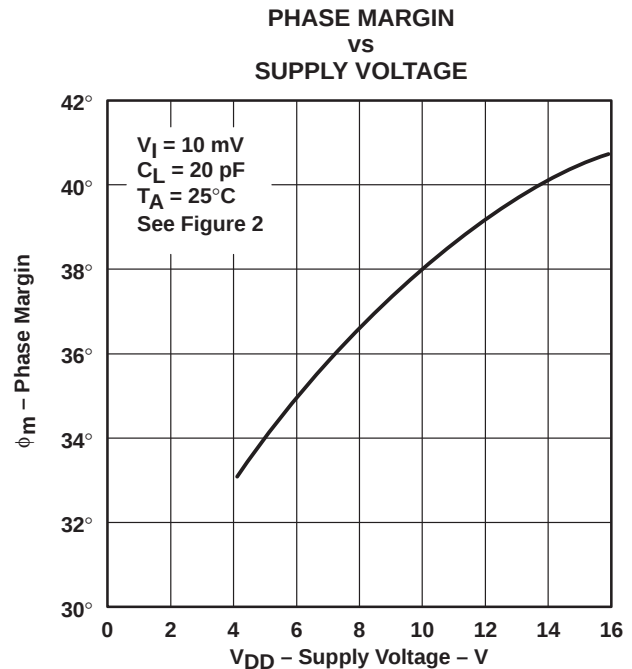


Figure 32

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

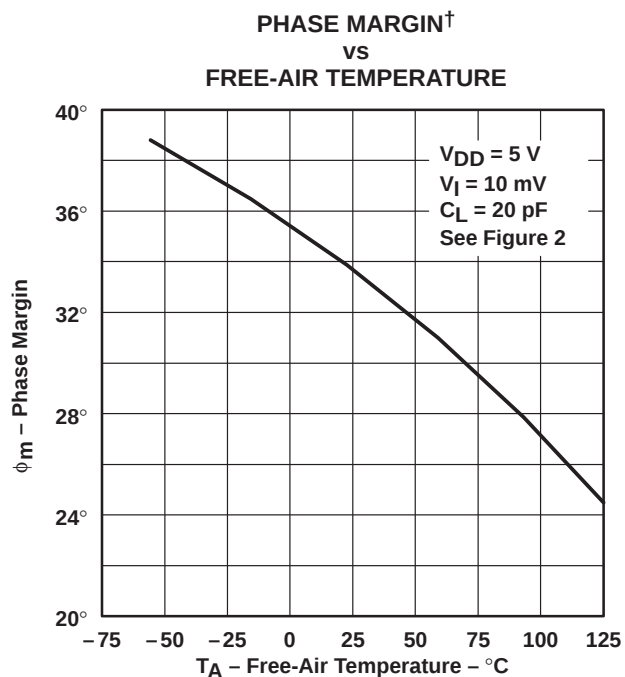


Figure 33

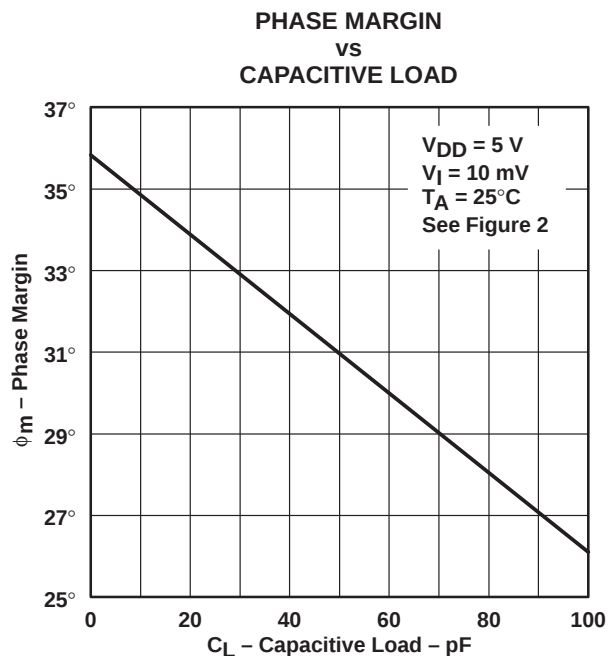


Figure 34

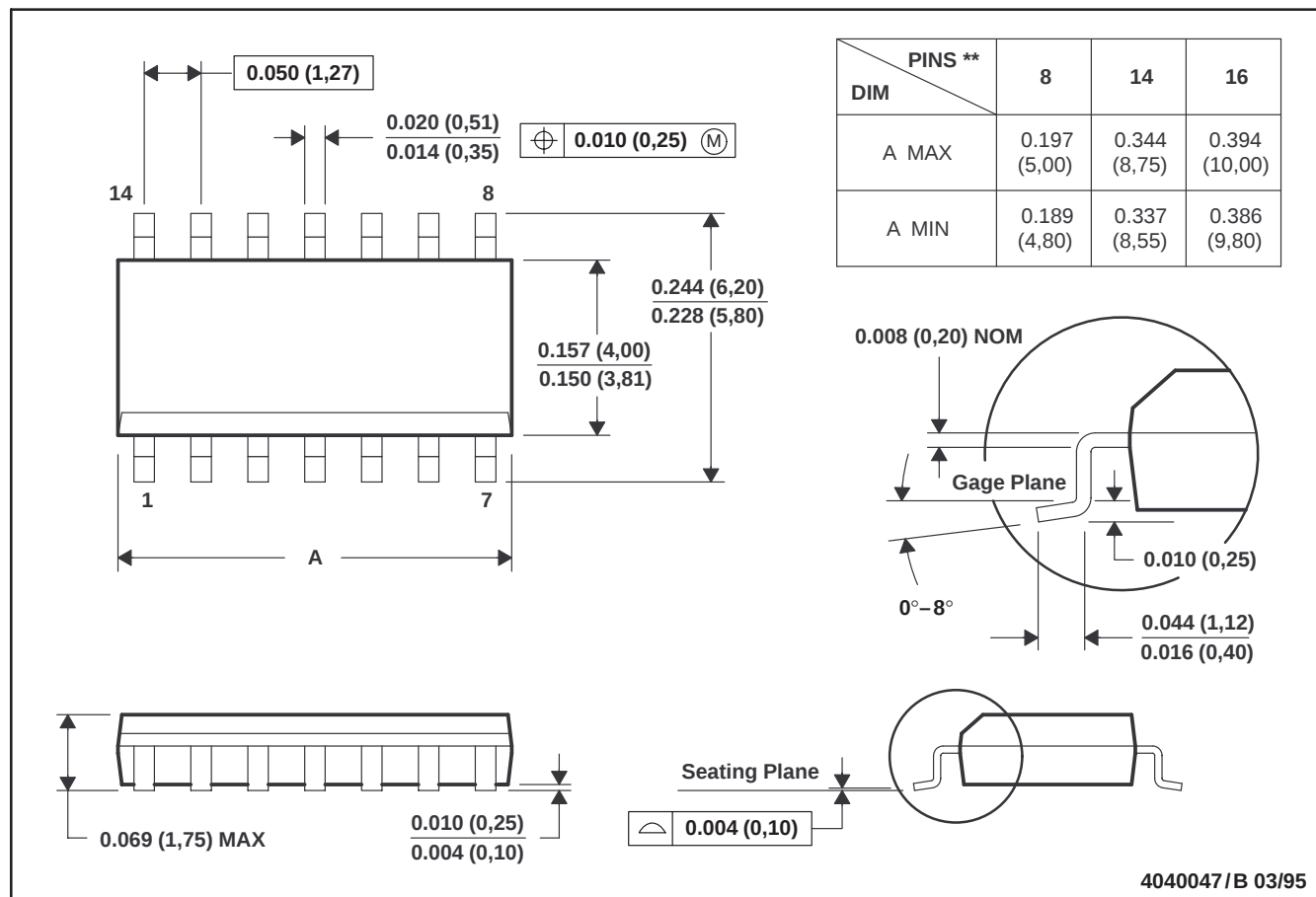
[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

MECHANICAL INFORMATION

D (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PIN SHOWN



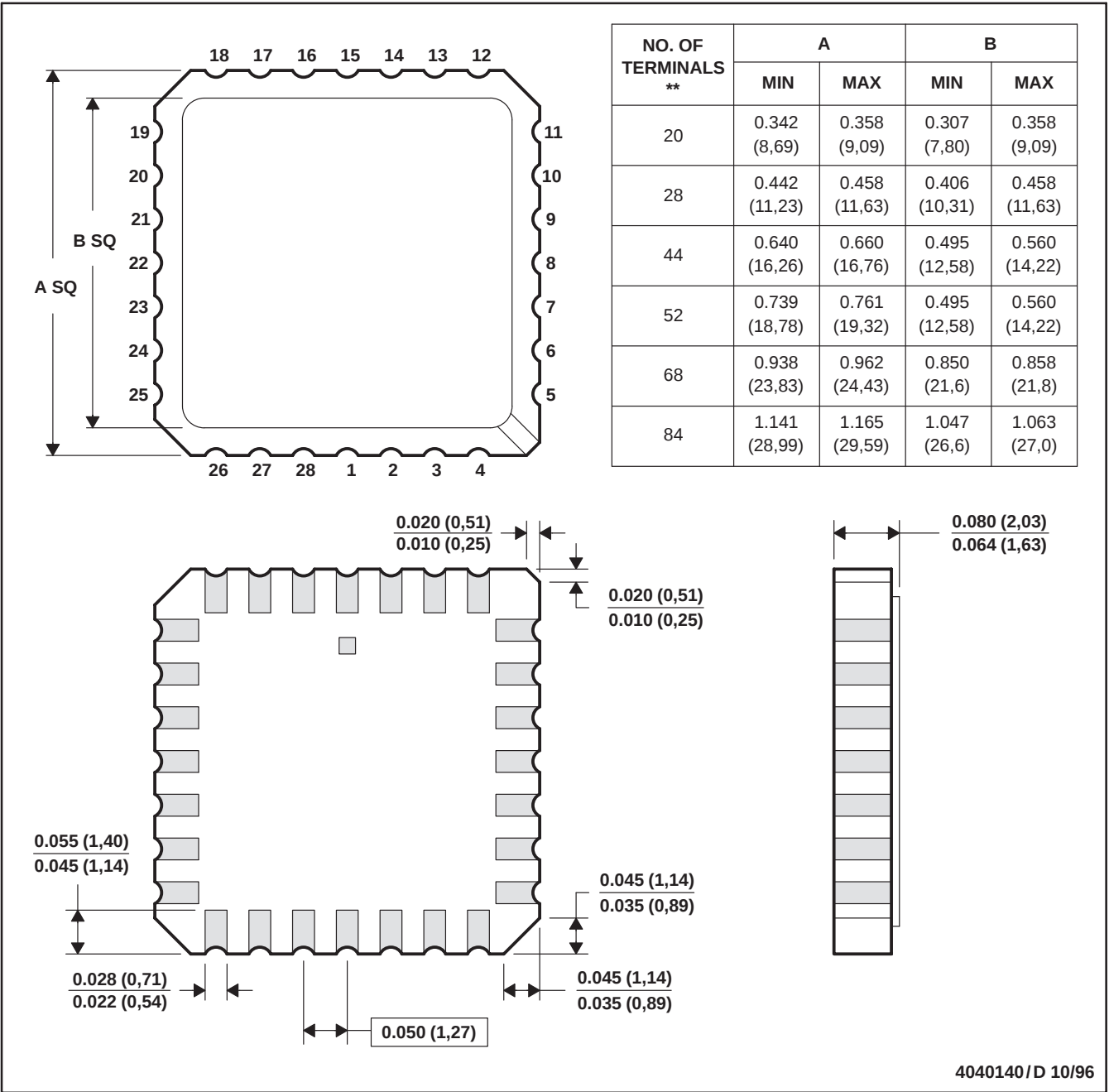
- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).
 - Four center pins are connected to die mount pad.
 - Falls within JEDEC MS-012

MECHANICAL INFORMATION

FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



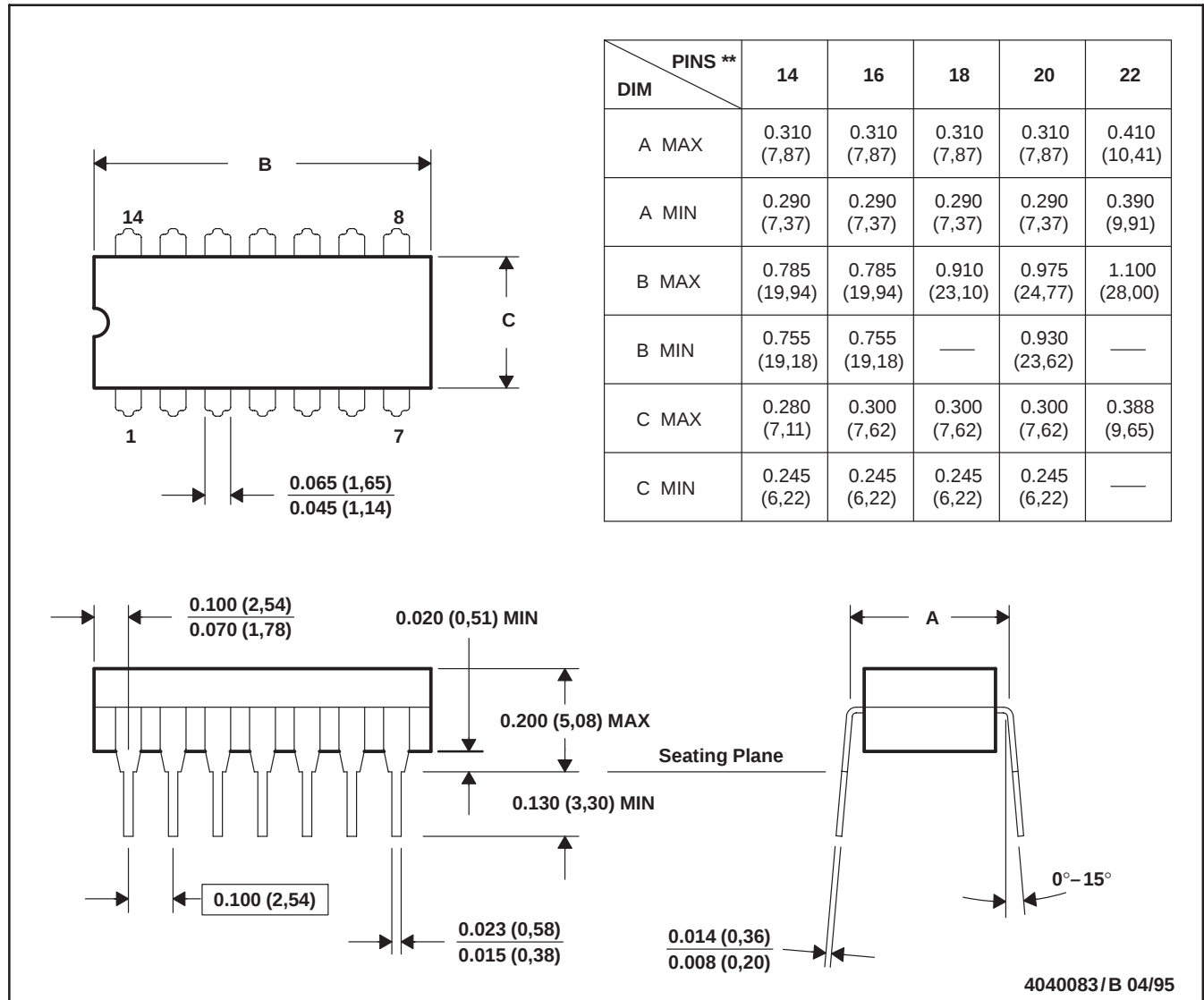
- NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package can be hermetically sealed with a metal lid.
D. The terminals are gold plated.
E. Falls within JEDEC MS-004

MECHANICAL INFORMATION

J (R-GDIP-T**)

CERAMIC DUAL-IN-LINE PACKAGE

14 PIN SHOWN



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package can be hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 - E. Falls within MIL-STD-1835 GDIP1-T14, GDIP1-T16, GDIP1-T18, GDIP1-T20, and GDIP1-T22

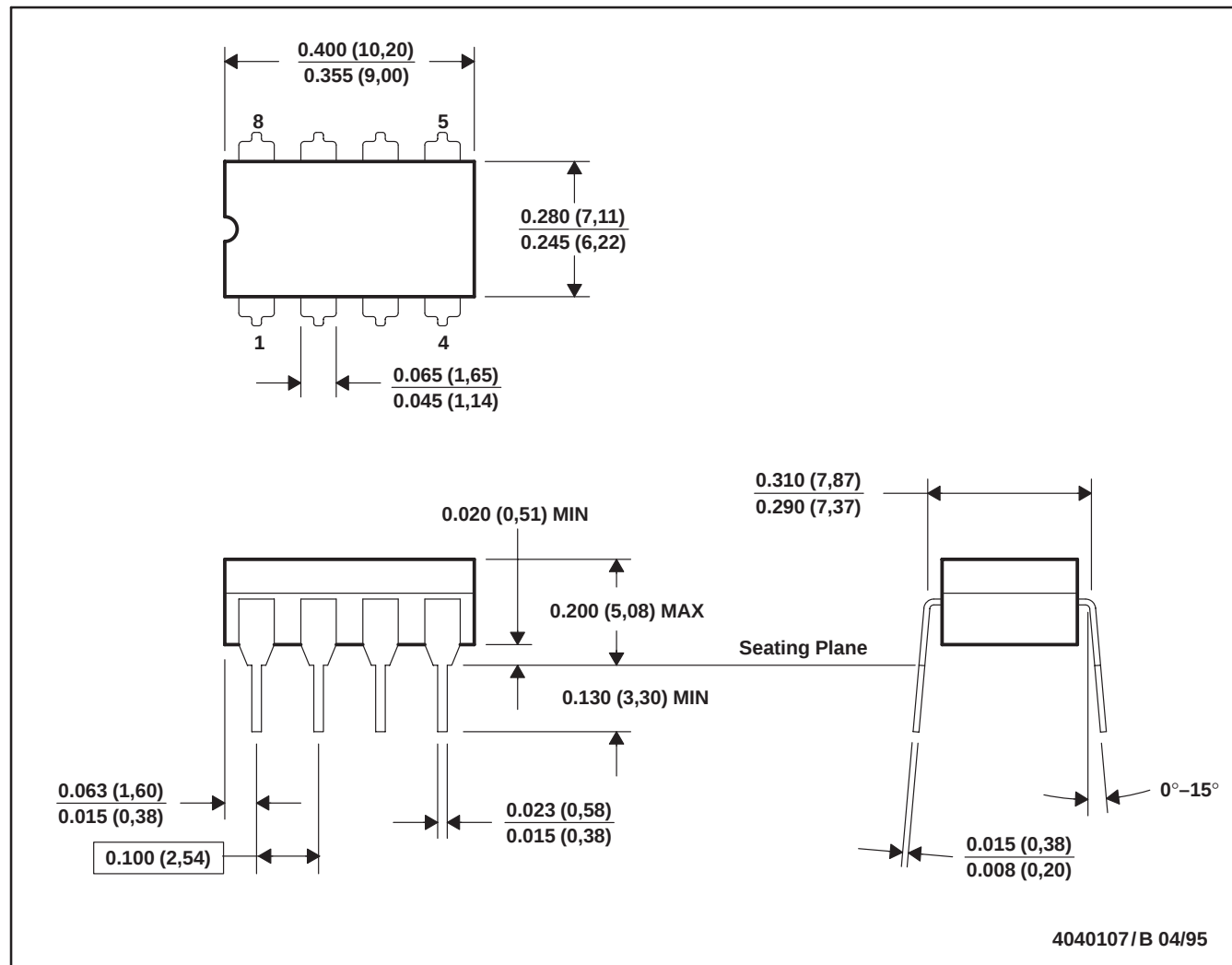
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MECHANICAL INFORMATION

JG (R-GDIP-T8)

CERAMIC DUAL-IN-LINE PACKAGE



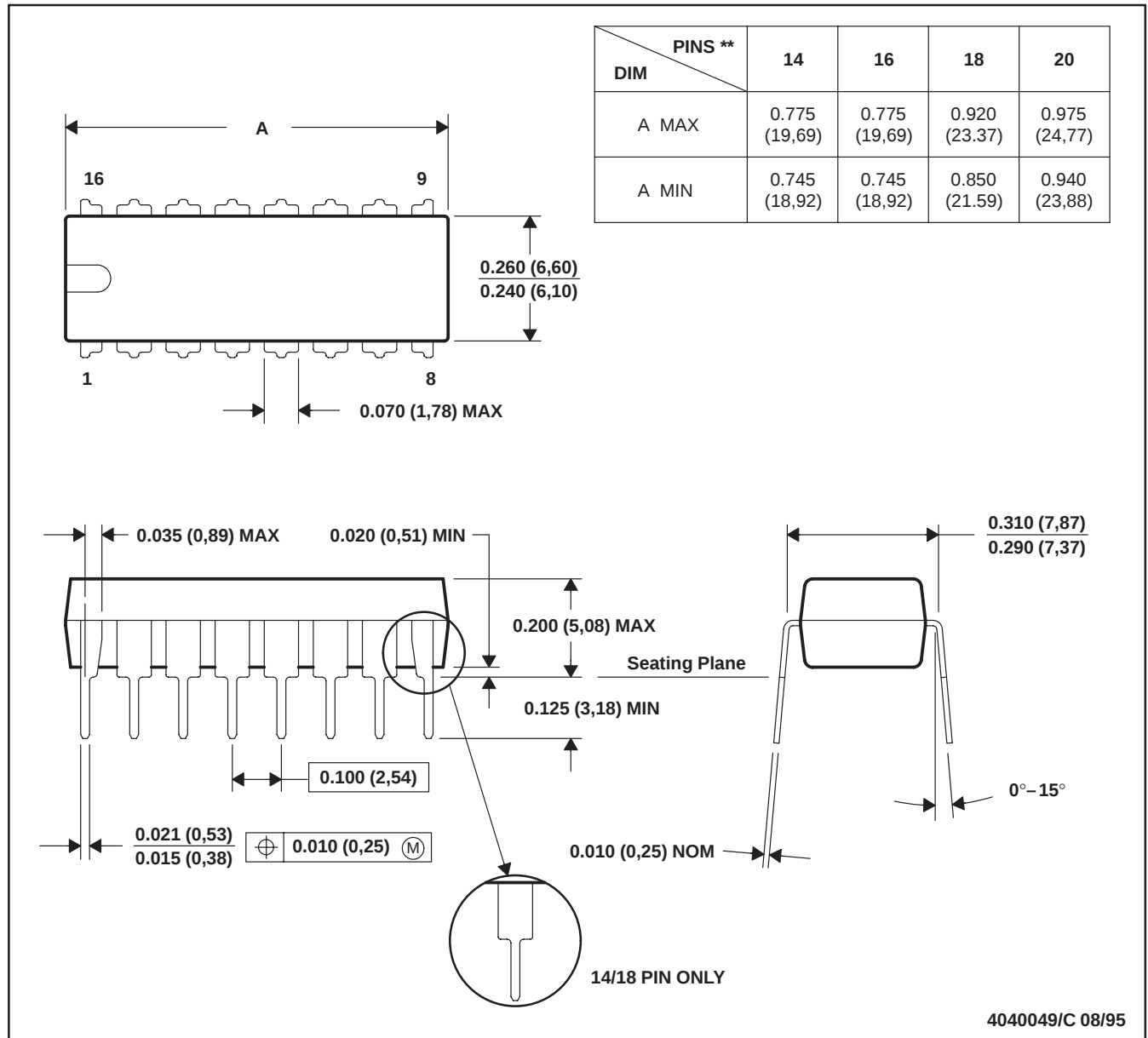
- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. This package can be hermetically sealed with a ceramic lid using glass frit.
 D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only
 E. Falls within MIL-STD-1835 GDIP1-T8

MECHANICAL INFORMATION

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PIN SHOWN



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Falls within JEDEC MS-001 (20 pin package is shorter than MS-001.)

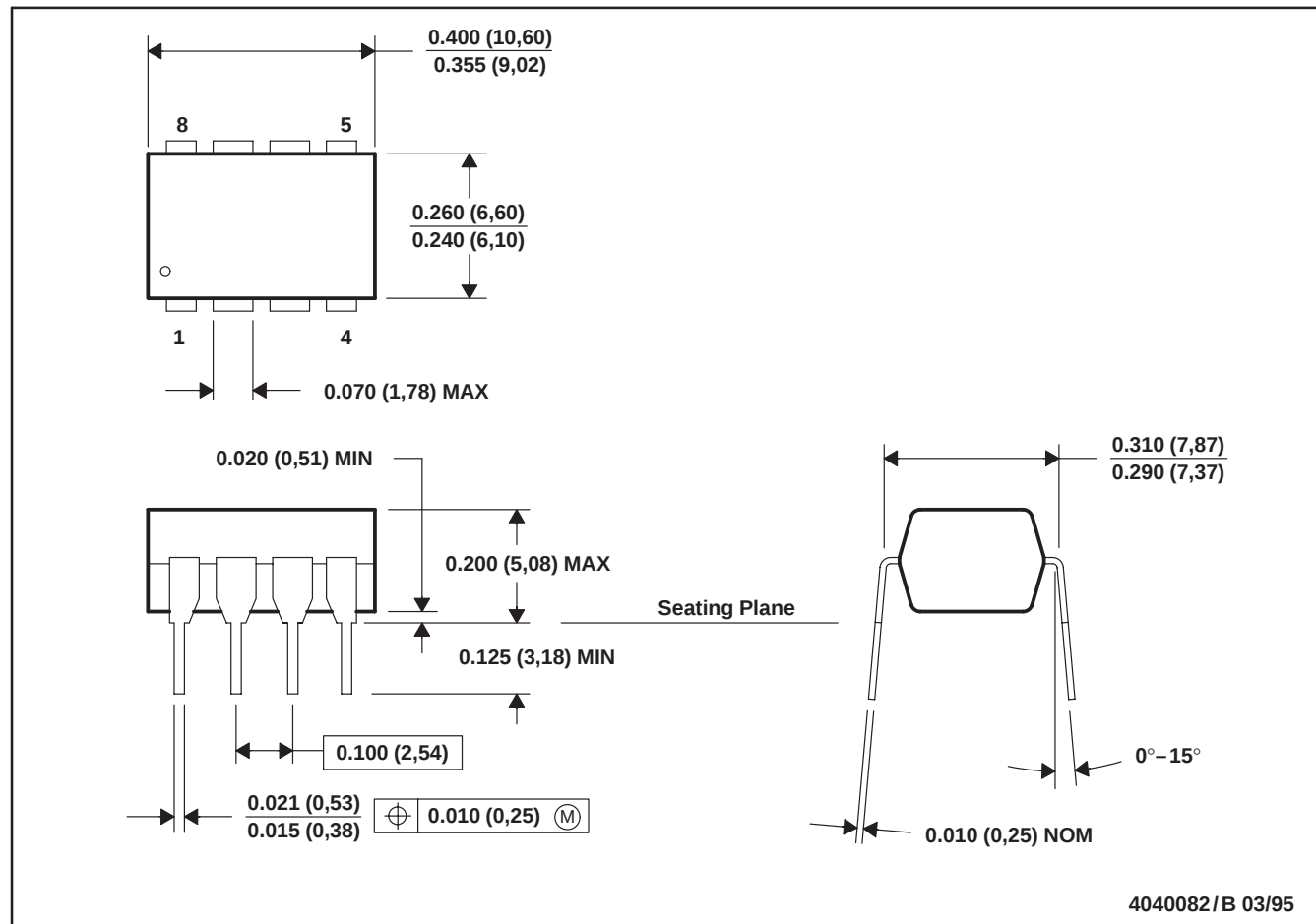
TLC1078, TLC1078Y, TLC1079, TLC1079Y
LinCMOS™ μ POWER PRECISION
OPERATIONAL AMPLIFIERS

SLOS179 – FEBRUARY 1997

MECHANICAL INFORMATION

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



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 B. This drawing is subject to change without notice.
 C. Falls within JEDEC MS-001

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